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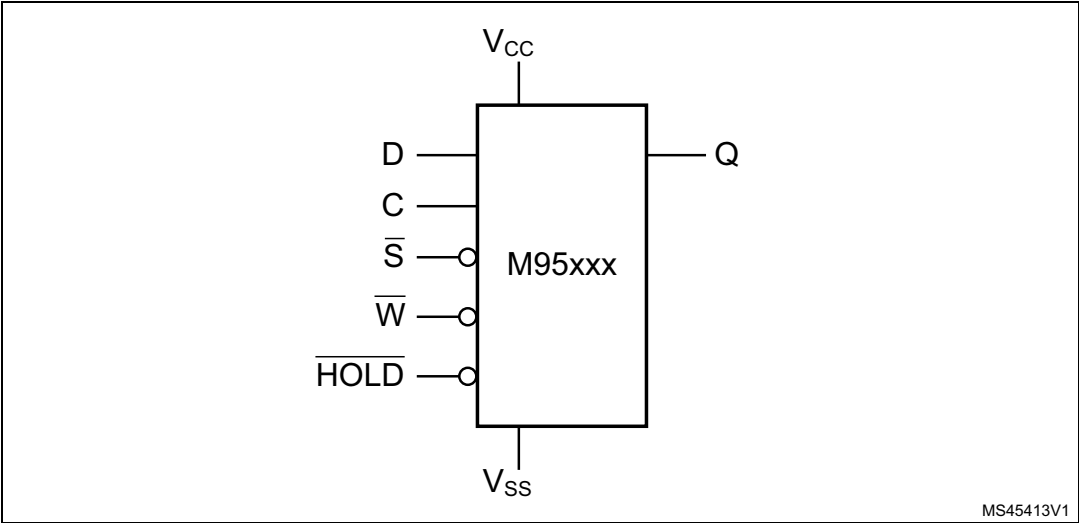
# 1 Description

The M95256 devices are Electrically Erasable PROgrammable Memories (EEPROMs) organized as 32768 x 8 bits, accessed through the SPI bus.

The M95256-W can operate with a supply voltage from 2.5 V to 5.5 V, the M95256-R can operate with a supply voltage from 1.8 V to 5.5 V and the M95256-DF can operate with a supply voltage from 1.7 V to 5.5 V, over an ambient temperature range of -40 °C / +85 °C.

The M95256-Dx offers an additional page, named the Identification Page (64 bytes). The Identification Page can be used to store sensitive application parameters that can be (later) permanently locked in Read-only mode.

Figure 1. Logic diagram

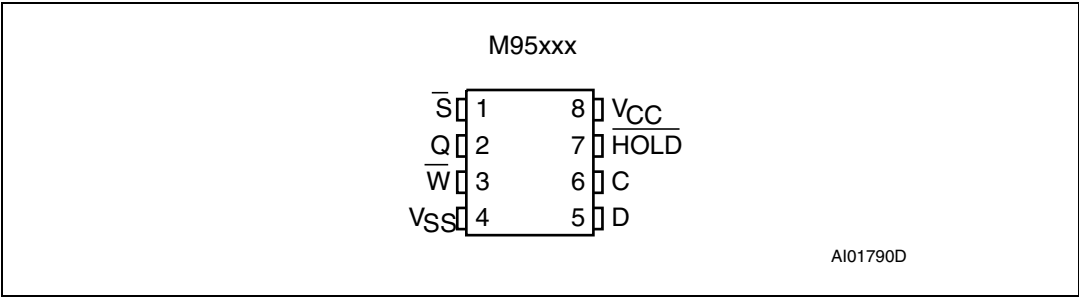


The SPI bus signals are C, D and Q, as shown in [Figure 1](#) and [Table 1](#). The device is selected when Chip Select ( $\overline{S}$ ) is driven low. Communications with the device can be interrupted when the  $\overline{HOLD}$  is driven low.

Table 1. Signal names

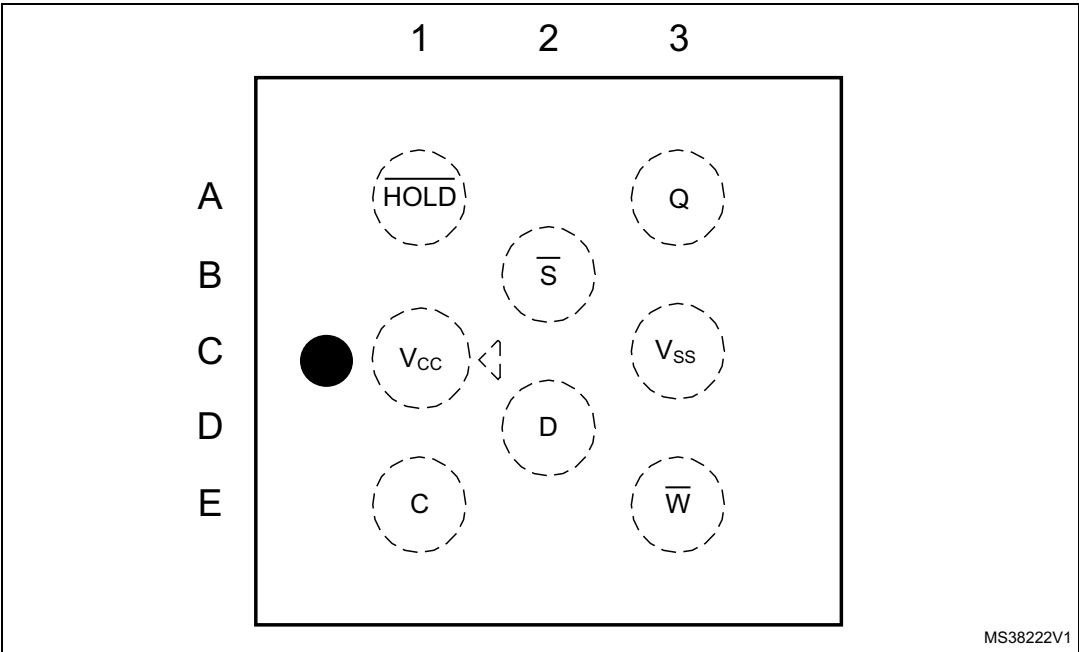
| Signal name       | Function           | Direction |
|-------------------|--------------------|-----------|
| C                 | Serial Clock       | Input     |
| D                 | Serial Data Input  | Input     |
| Q                 | Serial Data Output | Output    |
| $\overline{S}$    | Chip Select        | Input     |
| $\overline{W}$    | Write Protect      | Input     |
| $\overline{HOLD}$ | Hold               | Input     |
| V <sub>CC</sub>   | Supply voltage     | -         |
| V <sub>SS</sub>   | Ground             | -         |

Figure 2. 8-pin package connections (top view)



1. See [Section 10: Package information](#) for package dimensions, and how to identify pin-1.

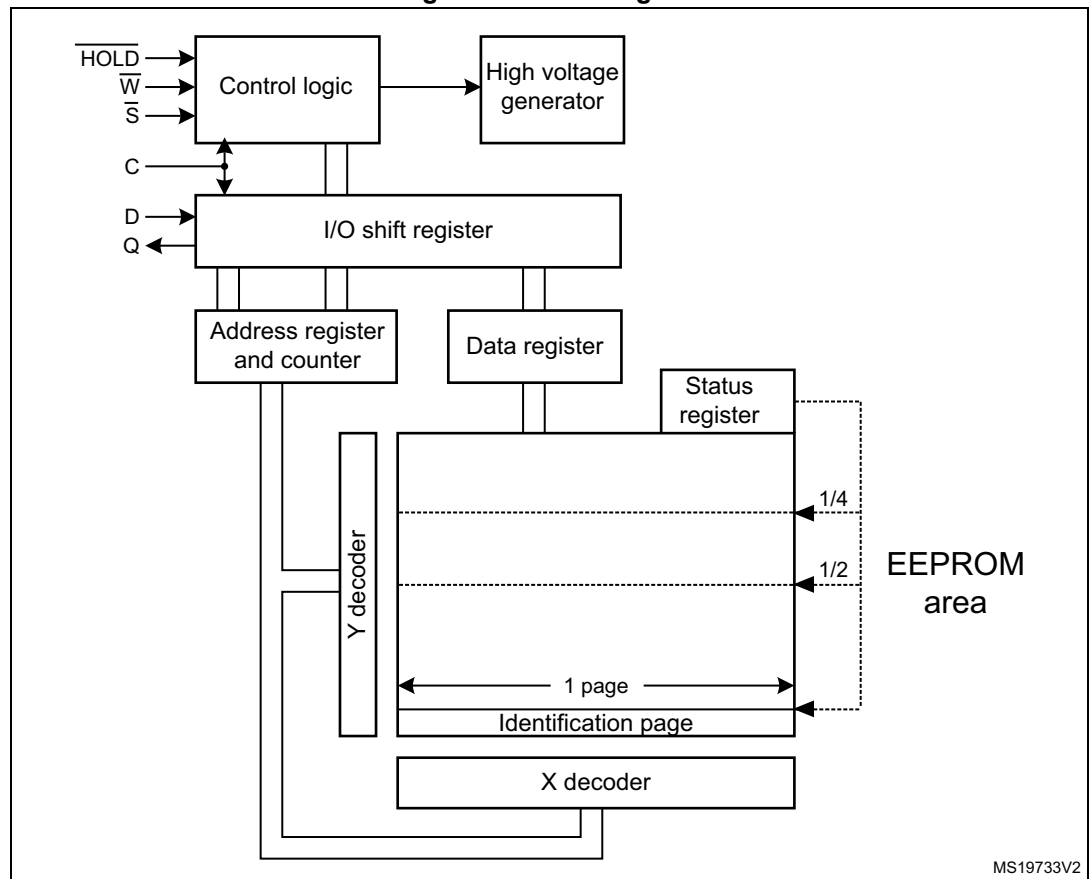
Figure 3. WLCSP connections (top view, marking side, with bumps on the underside)



## 2 Memory organization

The memory is organized as shown in the following figure.

**Figure 4. Block diagram**



## 3 Signal description

During all operations,  $V_{CC}$  must be held stable and within the specified valid range:  $V_{CC}(\min)$  to  $V_{CC}(\max)$ .

All of the input and output signals must be held high or low (according to voltages of  $V_{IH}$ ,  $V_{OH}$ ,  $V_{IL}$  or  $V_{OL}$ , as specified in [Section 9: DC and AC parameters](#)). These signals are described next.

### 3.1 Serial Data Output (Q)

This output signal is used to transfer data serially out of the device. Data is shifted out on the falling edge of Serial Clock (C).

### 3.2 Serial Data Input (D)

This input signal is used to transfer data serially into the device. It receives instructions, addresses, and the data to be written. Values are latched on the rising edge of Serial Clock (C).

### 3.3 Serial Clock (C)

This input signal provides the timing of the serial interface. Instructions, addresses, or data present at Serial Data Input (D) are latched on the rising edge of Serial Clock (C). Data on Serial Data Output (Q) change from the falling edge of Serial Clock (C).

### 3.4 Chip Select ( $\overline{S}$ )

When this input signal is high, the device is deselected and Serial Data Output (Q) is at high impedance. The device is in the Standby Power mode, unless an internal Write cycle is in progress. Driving Chip Select ( $\overline{S}$ ) low selects the device, placing it in the Active Power mode.

After power-up, a falling edge on Chip Select ( $\overline{S}$ ) is required prior to the start of any instruction.

### 3.5 Hold ( $\overline{HOLD}$ )

The Hold ( $\overline{HOLD}$ ) signal is used to pause any serial communications with the device without deselecting the device.

During the Hold condition, the Serial Data Output (Q) is high impedance, and Serial Data Input (D) and Serial Clock (C) are Don't Care.

To start the Hold condition, the device must be selected, with Chip Select ( $\overline{S}$ ) driven low.



### 3.6 Write Protect ( $\overline{W}$ )

The main purpose of this input signal is to freeze the size of the area of memory that is protected against Write instructions (as specified by the values in the BP1 and BP0 bits of the Status Register).

This pin must be driven either high or low, and must be stable during all Write instructions.

### 3.7 $V_{CC}$ supply voltage

$V_{CC}$  is the supply voltage.

### 3.8 $V_{SS}$ ground

$V_{SS}$  is the reference for all signals, including the  $V_{CC}$  supply voltage.



## 4.1 SPI modes

These devices can be driven by a microcontroller with its SPI peripheral running in either of the following two modes:

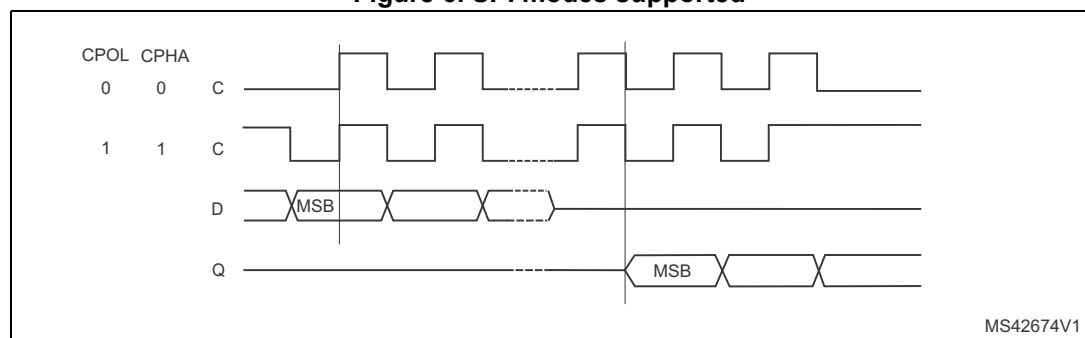
- CPOL=0, CPHA=0
- CPOL=1, CPHA=1

For these two modes, input data is latched in on the rising edge of Serial Clock (C), and output data is available from the falling edge of Serial Clock (C).

The difference between the two modes, as shown in [Figure 6](#), is the clock polarity when the bus master is in Stand-by mode and not transferring data:

- C remains at 0 for (CPOL=0, CPHA=0)
- C remains at 1 for (CPOL=1, CPHA=1)

**Figure 6. SPI modes supported**



## 5 Operating features

### 5.1 Supply voltage ( $V_{CC}$ )

#### 5.1.1 Operating supply voltage ( $V_{CC}$ )

Prior to selecting the memory and issuing instructions to it, a valid and stable  $V_{CC}$  voltage within the specified [ $V_{CC}(\min)$ ,  $V_{CC}(\max)$ ] range must be applied (see Operating conditions in [Section 9: DC and AC parameters](#)). This voltage must remain stable and valid until the end of the transmission of the instruction and, for a Write instruction, until the completion of the internal write cycle ( $t_W$ ). In order to secure a stable DC supply voltage, it is recommended to decouple the  $V_{CC}$  line with a suitable capacitor (usually of the order of 10 nF to 100 nF) close to the  $V_{CC}/V_{SS}$  device pins.

#### 5.1.2 Device reset

In order to prevent erroneous instruction decoding and inadvertent Write operations during power-up, a power-on-reset (POR) circuit is included. At power-up, the device does not respond to any instruction until  $V_{CC}$  reaches the POR threshold voltage. This threshold is lower than the minimum  $V_{CC}$  operating voltage (see Operating conditions in [Section 9](#)).

At power-up, when  $V_{CC}$  passes over the POR threshold, the device is reset and is in the following state:

- in Standby Power mode,
- deselected,
- Status Register values:
  - The Write Enable Latch (WEL) bit is reset to 0.
  - The Write In Progress (WIP) bit is reset to 0.
  - The SRWD, BP1 and BP0 bits remain unchanged (non-volatile bits).

It is important to note that the device must not be accessed until  $V_{CC}$  reaches a valid and stable level within the specified [ $V_{CC}(\min)$ ,  $V_{CC}(\max)$ ] range, as defined under Operating conditions in [Section 9](#).

#### 5.1.3 Power-up conditions

When the power supply is turned on,  $V_{CC}$  rises continuously from  $V_{SS}$  to  $V_{CC}$ . During this time, the Chip Select ( $\bar{S}$ ) line is not allowed to float but should follow the  $V_{CC}$  voltage. It is therefore recommended to connect the  $\bar{S}$  line to  $V_{CC}$  via a suitable pull-up resistor (see [Figure 5](#)).

In addition, the Chip Select ( $\bar{S}$ ) input offers a built-in safety feature, as the  $\bar{S}$  input is edge-sensitive as well as level-sensitive: after power-up, the device does not become selected until a falling edge has first been detected on Chip Select ( $\bar{S}$ ). This ensures that Chip Select ( $\bar{S}$ ) must have been high, prior to going low to start the first operation.

The  $V_{CC}$  voltage has to rise continuously from 0 V up to the minimum  $V_{CC}$  operating voltage defined under Operating conditions in [Section 9](#).

### 5.1.4 Power-down

During power-down (continuous decrease of the  $V_{CC}$  supply voltage below the minimum  $V_{CC}$  operating voltage defined under Operating conditions in [Section 9](#)), the device must be:

- deselected (Chip Select  $\overline{S}$  should be allowed to follow the voltage applied on  $V_{CC}$ ),
- in Standby Power mode (there should not be any internal write cycle in progress).

## 5.2 Active Power and Standby Power modes

When Chip Select ( $\overline{S}$ ) is low, the device is selected, and in the Active Power mode. The device consumes  $I_{CC}$ .

When Chip Select ( $\overline{S}$ ) is high, the device is deselected. If a Write cycle is not currently in progress, the device then goes into the Standby Power mode, and the device consumption drops to  $I_{CC1}$ , as specified in DC characteristics (see [Section 9](#)).

## 5.3 Hold condition

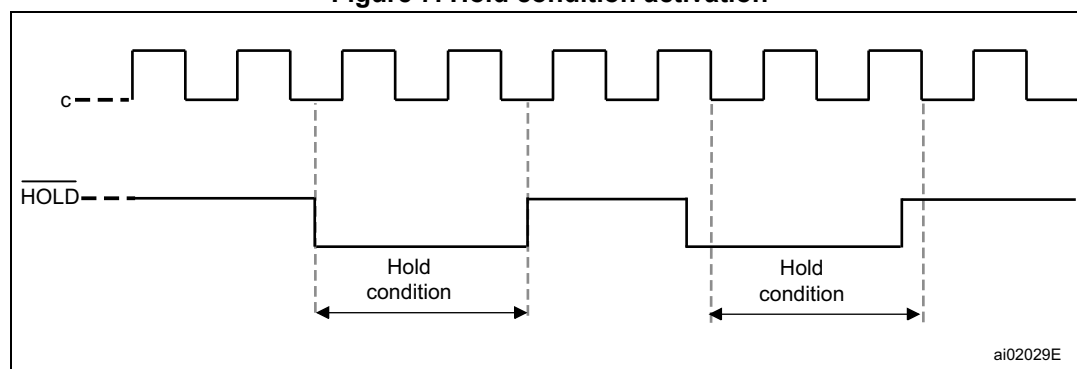
The Hold ( $\overline{HOLD}$ ) signal is used to pause any serial communications with the device without resetting the clocking sequence.

To enter the Hold condition, the device must be selected, with Chip Select ( $\overline{S}$ ) low.

During the Hold condition, the Serial Data Output (Q) is high impedance, and the Serial Data Input (D) and the Serial Clock (C) are Don't Care.

Normally, the device is kept selected for the whole duration of the Hold condition. Deselecting the device while it is in the Hold condition has the effect of resetting the state of the device, and this mechanism can be used if required to reset any processes that had been in progress.<sup>(a) (b)</sup>

**Figure 7. Hold condition activation**



a. This resets the internal logic, except the WEL and WIP bits of the Status Register.

b. In the specific case where the device has shifted in a Write command (Inst + Address + data bytes, each data byte being exactly 8 bits), deselecting the device also triggers the Write cycle of this decoded command.

The Hold condition starts when the Hold (HOLD) signal is driven low when Serial Clock (C) is already low (as shown in [Figure 7](#)).

The Hold condition ends when the Hold (HOLD) signal is driven high when Serial Clock (C) is already low.

[Figure 7](#) also shows what happens if the rising and falling edges are not timed to coincide with Serial Clock (C) being low.

## 5.4 Status Register

The Status Register contains a number of status and control bits that can be read or set (as appropriate) by specific instructions. See [Section 6.3: Read Status Register \(RDSR\)](#) for a detailed description of the Status Register bits.

## 5.5 Data protection and protocol control

The device features the following data protection mechanisms:

- Before accepting the execution of the Write and Write Status Register instructions, the device checks whether the number of clock pulses comprised in the instructions is a multiple of eight.
- All instructions that modify data must be preceded by a Write Enable (WREN) instruction to set the Write Enable Latch (WEL) bit.
- The Block Protect (BP1, BP0) bits in the Status Register are used to configure part of the memory as read-only.
- The Write Protect ( $\overline{W}$ ) signal is used to protect the Block Protect (BP1, BP0) bits in the Status Register.

For any instruction to be accepted, and executed, Chip Select ( $\overline{S}$ ) must be driven high after the rising edge of Serial Clock (C) for the last bit of the instruction, and before the next rising edge of Serial Clock (C).

Two points should be noted in the previous sentence:

- The “last bit of the instruction” can be the eighth bit of the instruction code, or the eighth bit of a data byte, depending on the instruction (except for Read Status Register (RDSR) and Read (READ) instructions).
- The “next rising edge of Serial Clock (C)” might (or might not) be the next bus transaction for some other device on the SPI bus.

**Table 2. Write-protected block size**

| Status Register bits |     | Protected block | Protected array addresses |
|----------------------|-----|-----------------|---------------------------|
| BP1                  | BP0 |                 |                           |
| 0                    | 0   | None            | None                      |
| 0                    | 1   | Upper quarter   | 6000h - 7FFFh             |
| 1                    | 0   | Upper half      | 4000h - 7FFFh             |
| 1                    | 1   | Whole memory    | 0000h - 7FFFh             |

## 6 Instructions

Each command is composed of bytes (MSBit transmitted first), initiated with the instruction byte, as summarized in [Table 3](#).

If an invalid instruction is sent (one not contained in [Table 3](#)), the device automatically enters in a Wait state until deselected.

**Table 3. Instruction set**

| Instruction         | Description                                     | Instruction format |
|---------------------|-------------------------------------------------|--------------------|
| WREN                | Write Enable                                    | 0000 0110          |
| WRDI                | Write Disable                                   | 0000 0100          |
| RDSR                | Read Status Register                            | 0000 0101          |
| WRSR                | Write Status Register                           | 0000 0001          |
| READ                | Read from Memory Array                          | 0000 0011          |
| WRITE               | Write to Memory Array                           | 0000 0010          |
| RDID <sup>(1)</sup> | Read Identification Page                        | 1000 0011          |
| WRID <sup>(1)</sup> | Write Identification Page                       | 1000 0010          |
| RDLS <sup>(1)</sup> | Reads the Identification Page lock status       | 1000 0011          |
| LID <sup>(1)</sup>  | Locks the Identification page in read-only mode | 1000 0010          |

1. Instruction available only for the M95256-D device.

For read and write commands to memory array and Identification Page the address is defined by two bytes as explained in [Table 4](#).

**Table 4. Significant bits within the two address bytes<sup>(1)(2)</sup>**

| Instructions  | MSB Address byte |     |     |     |     |     |    |    | LSB Address byte |    |    |    |    |    |    |    |
|---------------|------------------|-----|-----|-----|-----|-----|----|----|------------------|----|----|----|----|----|----|----|
|               | b15              | b14 | b13 | b12 | b11 | b10 | b9 | b8 | b7               | b6 | b5 | b4 | b3 | b2 | b1 | b0 |
| READ or WRITE | x                | A14 | A13 | A12 | A11 | A10 | A9 | A8 | A7               | A6 | A5 | A4 | A3 | A2 | A1 | A0 |
| RDID or WRID  | 0                | 0   | 0   | 0   | 0   | 0   | 0  | 0  | 0                | 0  | A5 | A4 | A3 | A2 | A1 | A0 |
| RDLS or LID   | 0                | 0   | 0   | 0   | 0   | 1   | 0  | 0  | 0                | 0  | 0  | 0  | 0  | 0  | 0  | 0  |

1. A: Significant address bit.

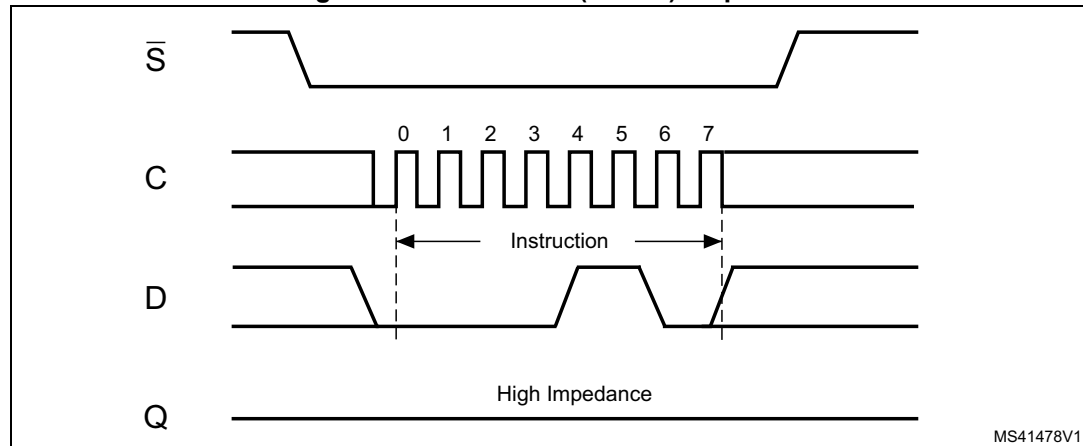
2. x: bit is Don't Care.

## 6.1 Write Enable (WREN)

The Write Enable Latch (WEL) bit must be set prior to each WRITE and WRSR instruction. The only way to do this is to send a Write Enable instruction to the device.

As shown in [Figure 8](#), to send this instruction to the device, Chip Select ( $\overline{S}$ ) is driven low, and the bits of the instruction byte are shifted in, on Serial Data Input (D). The device then enters a wait state. It waits for the device to be deselected by Chip Select ( $\overline{S}$ ) being driven high.

Figure 8. Write Enable (WREN) sequence





## 6.2 Write Disable (WRDI)

One way of resetting the Write Enable Latch (WEL) bit is to send a Write Disable instruction to the device.

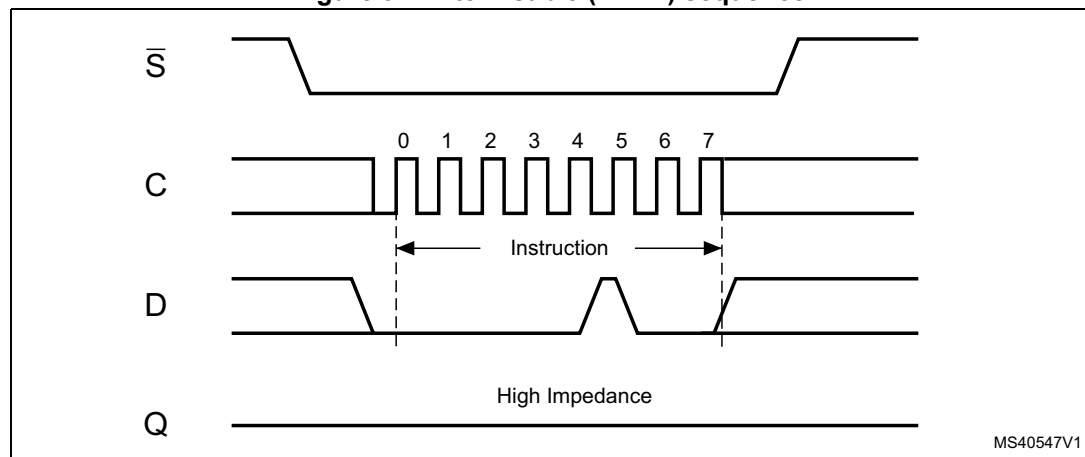
As shown in [Figure 9](#), to send this instruction to the device, Chip Select ( $\overline{S}$ ) is driven low, and the bits of the instruction byte are shifted in, on Serial Data Input (D).

The device then enters a wait state. It waits for the device to be deselected, by Chip Select ( $\overline{S}$ ) being driven high.

The Write Enable Latch (WEL) bit, in fact, becomes reset by any of the following events:

- Power-up
- WRDI instruction execution
- WRSR instruction completion
- WRITE instruction completion.

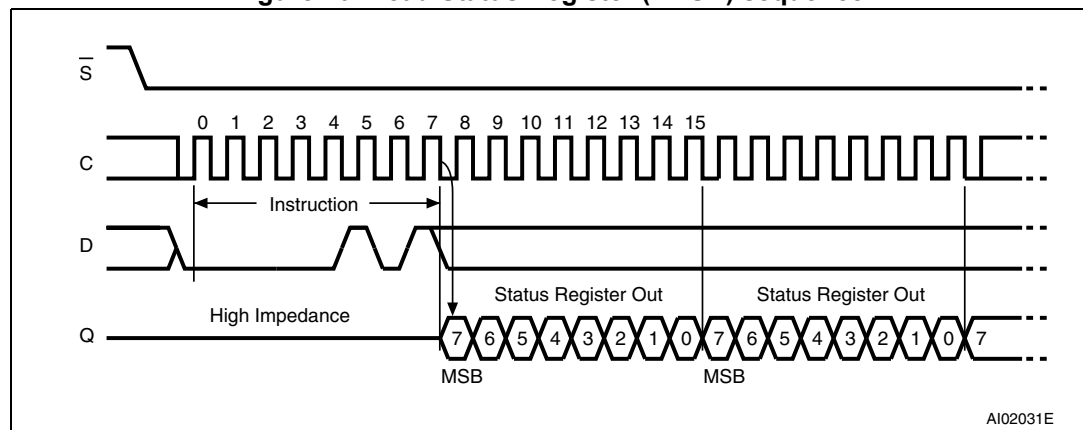
**Figure 9. Write Disable (WRDI) sequence**



### 6.3 Read Status Register (RDSR)

The Read Status Register (RDSR) instruction is used to read the Status Register. The Status Register may be read at any time, even while a Write or Write Status Register cycle is in progress. When one of these cycles is in progress, it is recommended to check the Write In Progress (WIP) bit before sending a new instruction to the device. It is also possible to read the Status Register continuously, as shown in [Figure 10](#).

**Figure 10. Read Status Register (RDSR) sequence**



The status and control bits of the Status Register are as follows:

#### 6.3.1 WIP bit

The Write In Progress (WIP) bit indicates whether the memory is busy with a Write or Write Status Register cycle. When set to 1, such a cycle is in progress, when reset to 0, no such cycle is in progress.

#### 6.3.2 WEL bit

The Write Enable Latch (WEL) bit indicates the status of the internal Write Enable Latch. When set to 1, the internal Write Enable Latch is set. When set to 0, the internal Write Enable Latch is reset, and no Write or Write Status Register instruction is accepted.

The WEL bit is returned to its reset state by the following events:

- Power-up
- Write Disable (WRDI) instruction completion
- Write Status Register (WRSR) instruction completion
- Write (WRITE) instruction completion

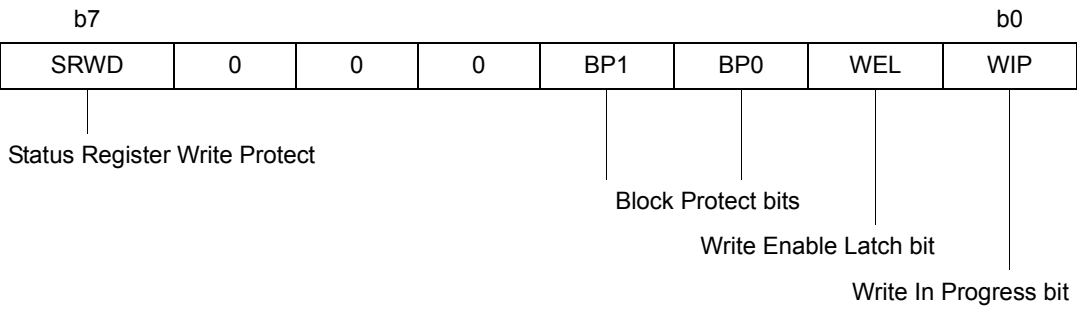
#### 6.3.3 BP1, BP0 bits

The Block Protect (BP1, BP0) bits are non volatile. They define the size of the area to be software-protected against Write instructions. These bits are written with the Write Status Register (WRSR) instruction. When one or both of the Block Protect (BP1, BP0) bits is set to 1, the relevant memory area (as defined in [Table 2](#)) becomes protected against Write (WRITE) instructions. The Block Protect (BP1, BP0) bits can be written provided that the Hardware Protected mode has not been set.

6.3.4 SRWD bit

The Status Register Write Disable (SRWD) bit is operated in conjunction with the Write Protect ( $\overline{W}$ ) signal. The Status Register Write Disable (SRWD) bit and Write Protect ( $\overline{W}$ ) signal enable the device to be put in the Hardware Protected mode (when the Status Register Write Disable (SRWD) bit is set to 1, and Write Protect ( $\overline{W}$ ) is driven low). In this mode, the non-volatile bits of the Status Register (SRWD, BP1, BP0) become read-only bits and the Write Status Register (WRSR) instruction is no longer accepted for execution.

Table 5. Status Register format



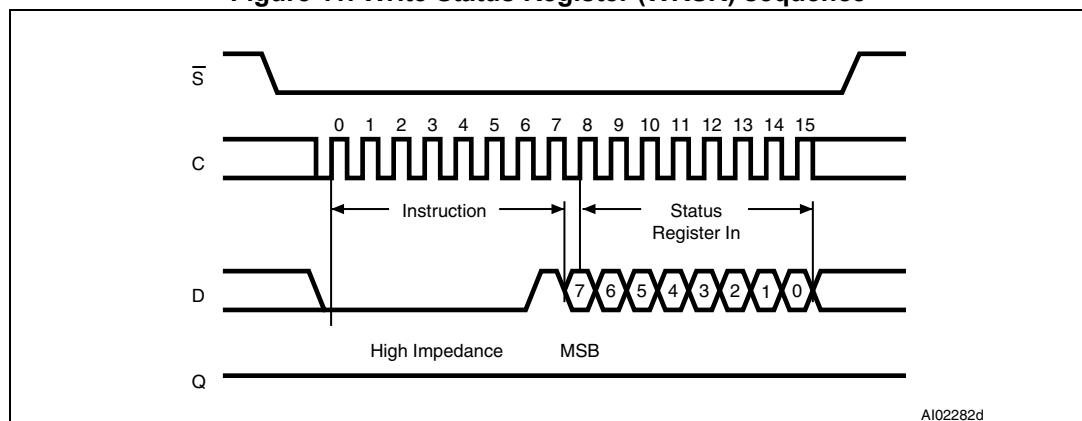
## 6.4 Write Status Register (WRSR)

The Write Status Register (WRSR) instruction is used to write new values to the Status Register. Before it can be accepted, a Write Enable (WREN) instruction must have been previously executed.

The Write Status Register (WRSR) instruction is entered by driving Chip Select ( $\overline{S}$ ) low, followed by the instruction code, the data byte on Serial Data input (D) and Chip Select ( $\overline{S}$ ) driven high. Chip Select ( $\overline{S}$ ) must be driven high after the rising edge of Serial Clock (C) that latches in the eighth bit of the data byte, and before the next rising edge of Serial Clock (C). Otherwise, the Write Status Register (WRSR) instruction is not executed.

The instruction sequence is shown in [Figure 11](#).

**Figure 11. Write Status Register (WRSR) sequence**



Driving the Chip Select ( $\overline{S}$ ) signal high at a byte boundary of the input data triggers the self-timed Write cycle that takes  $t_{WV}$  to complete (as specified in AC tables under [Section 9: DC and AC parameters](#)).

While the Write Status Register cycle is in progress, the Status Register may still be read to check the value of the Write in progress (WIP) bit: the WIP bit is 1 during the self-timed Write cycle  $t_{WV}$ , and 0 when the Write cycle is complete. The WEL bit (Write Enable Latch) is also reset at the end of the Write cycle  $t_{WV}$ .

The Write Status Register (WRSR) instruction enables the user to change the values of the BP1, BP0 and SRWD bits:

- The Block Protect (BP1, BP0) bits define the size of the area that is to be treated as read-only, as defined in [Table 2](#).
- The SRWD (Status Register Write Disable) bit, in accordance with the signal read on the Write Protect pin ( $\overline{W}$ ), enables the user to set or reset the Write protection mode of the Status Register itself, as defined in [Table 6](#). When in Write-protected mode, the Write Status Register (WRSR) instruction is not executed.

The contents of the SRWD and BP1, BP0 bits are updated after the completion of the WRSR instruction, including the  $t_{WV}$  Write cycle.

The Write Status Register (WRSR) instruction has no effect on the b6, b5, b4, b1, b0 bits in the Status Register. Bits b6, b5, b4 are always read as 0.

Table 6. Protection modes

| $\overline{W}$ signal | SRWD bit | Mode                     | Write protection of the Status Register                                                                                       | Memory content                |                                    |
|-----------------------|----------|--------------------------|-------------------------------------------------------------------------------------------------------------------------------|-------------------------------|------------------------------------|
|                       |          |                          |                                                                                                                               | Protected area <sup>(1)</sup> | Unprotected area <sup>(1)</sup>    |
| 1                     | 0        | Software-protected (SPM) | Status Register is writable (if the WREN instruction has set the WEL bit). The values in the BP1 and BP0 bits can be changed. | Write-protected               | Ready to accept Write instructions |
| 0                     | 0        |                          |                                                                                                                               |                               |                                    |
| 1                     | 1        | Hardware-protected (HPM) | Status Register is Hardware write-protected. The values in the BP1 and BP0 bits cannot be changed.                            | Write-protected               | Ready to accept Write instructions |
| 0                     | 1        |                          |                                                                                                                               |                               |                                    |

1. As defined by the values in the Block Protect (BP1, BP0) bits of the Status Register. See [Table 2](#).

The protection features of the device are summarized in [Table 6](#).

When the Status Register Write Disable (SRWD) bit in the Status Register is 0 (its initial delivery state), it is possible to write to the Status Register (provided that the WEL bit has previously been set by a WREN instruction), regardless of the logic level applied on the Write Protect ( $\overline{W}$ ) input pin.

When the Status Register Write Disable (SRWD) bit in the Status Register is set to 1, two cases should be considered, depending on the state of the Write Protect ( $\overline{W}$ ) input pin:

- If Write Protect ( $\overline{W}$ ) is driven high, it is possible to write to the Status Register (provided that the WEL bit has previously been set by a WREN instruction).
- If Write Protect ( $\overline{W}$ ) is driven low, it is not possible to write to the Status Register even if the WEL bit has previously been set by a WREN instruction. (Attempts to write to the Status Register are rejected, and are not accepted for execution). As a consequence, all the data bytes in the memory area, which are Software-protected (SPM) by the Block Protect (BP1, BP0) bits in the Status Register, are also hardware-protected against data modification.

Regardless of the order of the two events, the Hardware-protected mode (HPM) can be entered by:

- either setting the SRWD bit after driving the Write Protect ( $\overline{W}$ ) input pin low,
- or driving the Write Protect ( $\overline{W}$ ) input pin low after setting the SRWD bit.

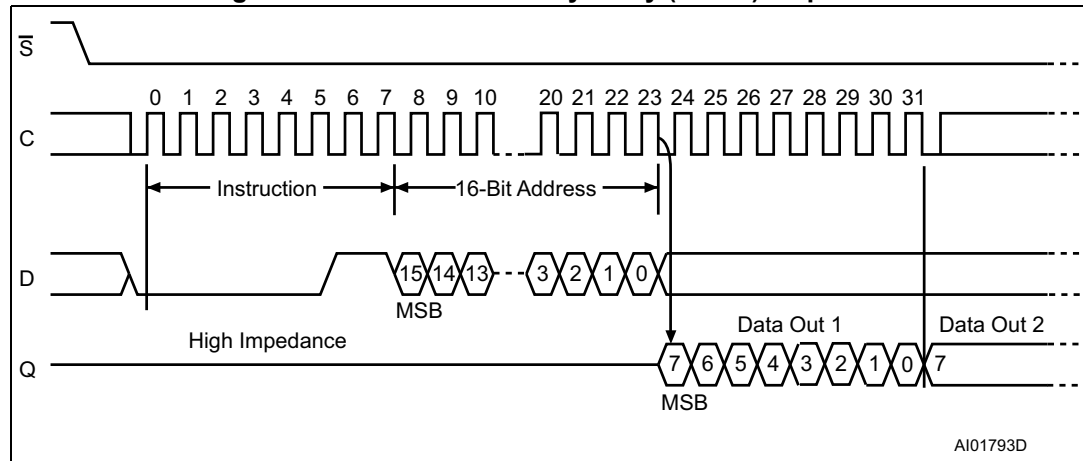
Once the Hardware-protected mode (HPM) has been entered, the only way of exiting it is to pull high the Write Protect ( $\overline{W}$ ) input pin.

If the Write Protect ( $\overline{W}$ ) input pin is permanently tied high, the Hardware-protected mode (HPM) can never be activated, and only the Software-protected mode (SPM), using the Block Protect (BP1, BP0) bits in the Status Register, can be used.

## 6.5 Read from Memory Array (READ)

As shown in [Figure 12](#), to send this instruction to the device, Chip Select ( $\bar{S}$ ) is first driven low. The bits of the instruction byte and address bytes are then shifted in, on Serial Data Input (D). The address is loaded into an internal address register, and the byte of data at that address is shifted out, on Serial Data Output (Q).

**Figure 12. Read from Memory Array (READ) sequence**



1. Depending on the memory size, as shown in [Table 4](#), the most significant address bits are Don't Care.

If Chip Select ( $\bar{S}$ ) continues to be driven low, the internal address register is incremented automatically, and the byte of data at the new address is shifted out.

When the highest address is reached, the address counter rolls over to zero, allowing the Read cycle to be continued indefinitely. The whole memory can, therefore, be read with a single READ instruction.

The Read cycle is terminated by driving Chip Select ( $\bar{S}$ ) high. The rising edge of the Chip Select ( $\bar{S}$ ) signal can occur at any time during the cycle.

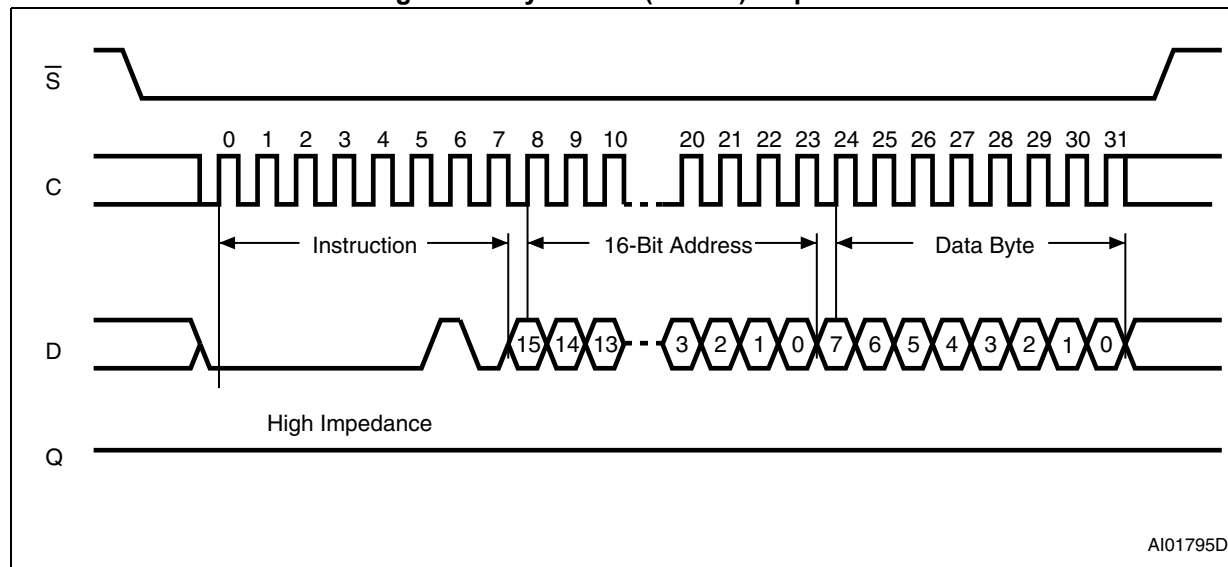
The instruction is not accepted, and is not executed, if a Write cycle is currently in progress.

## 6.6 Write to Memory Array (WRITE)

As shown in [Figure 13](#), to send this instruction to the device, Chip Select ( $\overline{S}$ ) is first driven low. The bits of the instruction byte, address byte, and at least one data byte are then shifted in, on Serial Data Input (D).

The instruction is terminated by driving Chip Select ( $\overline{S}$ ) high at a byte boundary of the input data. The self-timed Write cycle, triggered by the Chip Select ( $\overline{S}$ ) rising edge, continues for a period  $t_{WV}$  (as specified in AC characteristics in [Section 9: DC and AC parameters](#)), at the end of which the Write in Progress (WIP) bit is reset to 0.

**Figure 13. Byte Write (WRITE) sequence**



1. Depending on the memory size, as shown in [Table 4](#), the most significant address bits are Don't Care.

In the case of [Figure 13](#), Chip Select ( $\overline{S}$ ) is driven high after the eighth bit of the data byte has been latched in, indicating that the instruction is being used to write a single byte. However, if Chip Select ( $\overline{S}$ ) continues to be driven low, as shown in [Figure 14](#), the next byte of input data is shifted in, so that more than a single byte, starting from the given address towards the end of the same page, can be written in a single internal Write cycle.

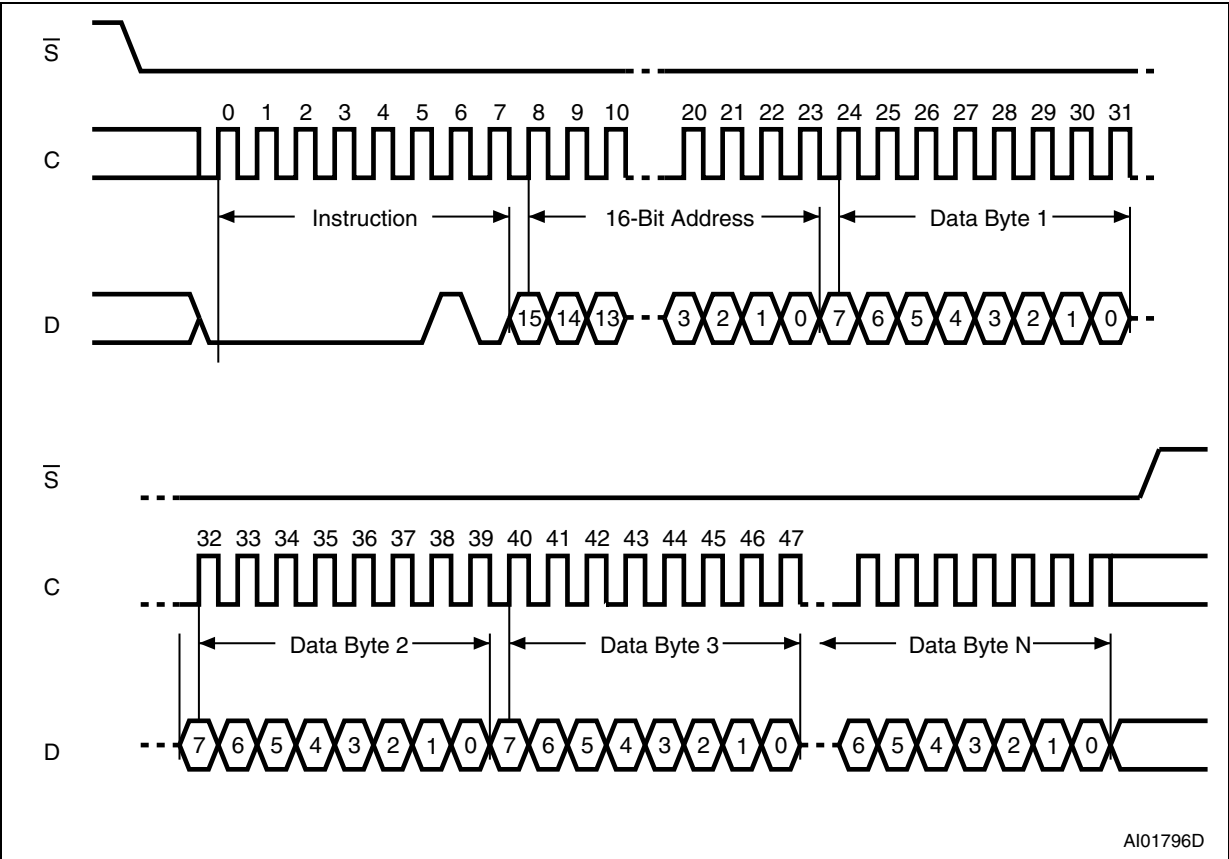
Each time a new data byte is shifted in, the least significant bits of the internal address counter are incremented. If more bytes are sent than will fit up to the end of the page, a condition known as "roll-over" occurs. In case of roll-over, the bytes exceeding the page size are overwritten from location 0 of the same page.

The instruction is not accepted, and is not executed, under the following conditions:

- if the Write Enable Latch (WEL) bit has not been set to 1 (by executing a Write Enable instruction just before),
- if a Write cycle is already in progress,
- if the device has not been deselected, by driving high Chip Select ( $\overline{S}$ ), at a byte boundary (after the eighth bit, b0, of the last data byte that has been latched in),
- if the addressed page is in the region protected by the Block Protect (BP1 and BP0) bits.

*Note:* The self-timed write cycle  $t_W$  is internally executed as a sequence of two consecutive events: [Erase addressed byte(s)], followed by [Program addressed byte(s)]. An erased bit is read as “0” and a programmed bit is read as “1”.

Figure 14. Page Write (WRITE) sequence



1. Depending on the memory size, as shown in [Table 4](#), the most significant address bits are Don't Care.



### 6.6.1 Cycling with Error Correction Code (ECC)

M95256 and M95256-D devices offer an Error Correction Code (ECC) logic. The ECC is an internal logic function transparent for the SPI communication protocol.

The ECC logic is implemented on each group of four EEPROM bytes<sup>(c)</sup>. Inside a group, if a single bit out of the four bytes happens to be erroneous during a Read operation, the ECC detects this bit and replaces it with the correct value. The read reliability is therefore much improved.

Even if the ECC function is performed on groups of four bytes, a single byte can be written/cycled independently. In this case, the ECC function also writes/cycles the three other bytes located in the same group<sup>(c)</sup>. As a consequence, the maximum cycling budget is defined at group level and the cycling can be distributed over the four bytes of the group: the sum of the cycles seen by byte0, byte1, byte2 and byte3 of the same group must remain below the maximum value defined in [Table 12](#).

---

c. A group of four bytes is located at addresses  $[4*N, 4*N+1, 4*N+2, 4*N+3]$ , where N is an integer.

## 6.7 Read Identification Page (available only in M95256-D devices)

The Identification Page (64 bytes) is an additional page that can be written and (later) permanently locked in Read-only mode.

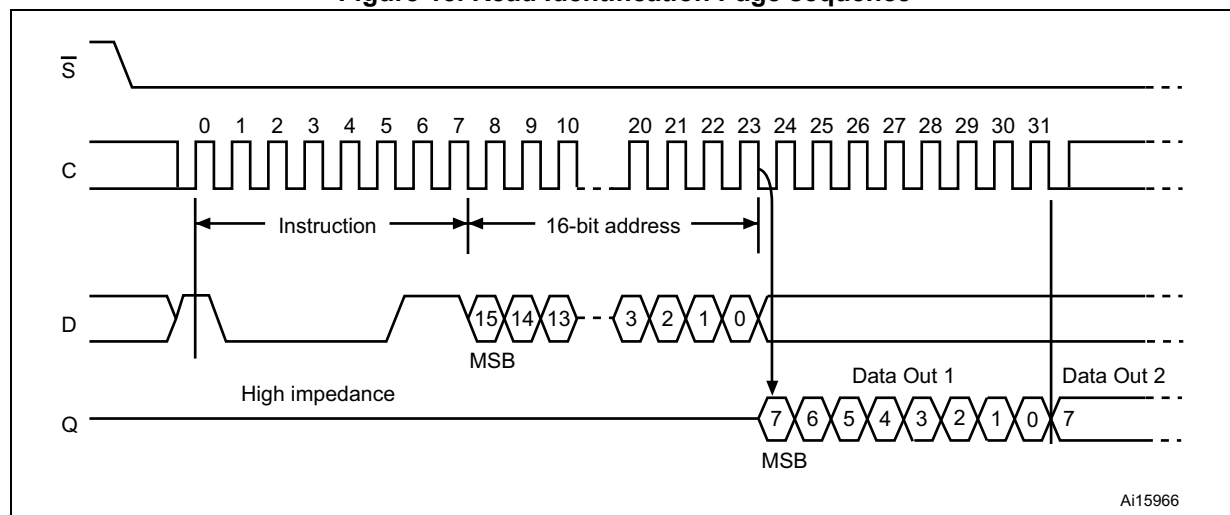
Reading this page is achieved with the Read Identification Page instruction (see [Table 3](#)). The Chip Select signal ( $\overline{S}$ ) is first driven low, the bits of the instruction byte and address bytes are then shifted in, on Serial Data Input (D). Address bit A10 must be 0, upper address bits are Don't Care, and the data byte pointed to by the lower address bits [A5:A0] is shifted out on Serial Data Output (Q). If Chip Select ( $\overline{S}$ ) continues to be driven low, the internal address register is automatically incremented, and the byte of data at the new address is shifted out.

The number of bytes to read in the ID page must not exceed the page boundary, otherwise unexpected data is read (e.g.: when reading the ID page from location 24d, the number of bytes should be less than or equal to 40d, as the ID page boundary is 64 bytes).

The read cycle is terminated by driving Chip Select ( $\overline{S}$ ) high. The rising edge of the Chip Select ( $\overline{S}$ ) signal can occur at any time during the cycle. The first byte addressed can be any byte within any page.

The instruction is not accepted, and is not executed, if a write cycle is currently in progress.

**Figure 15. Read Identification Page sequence**

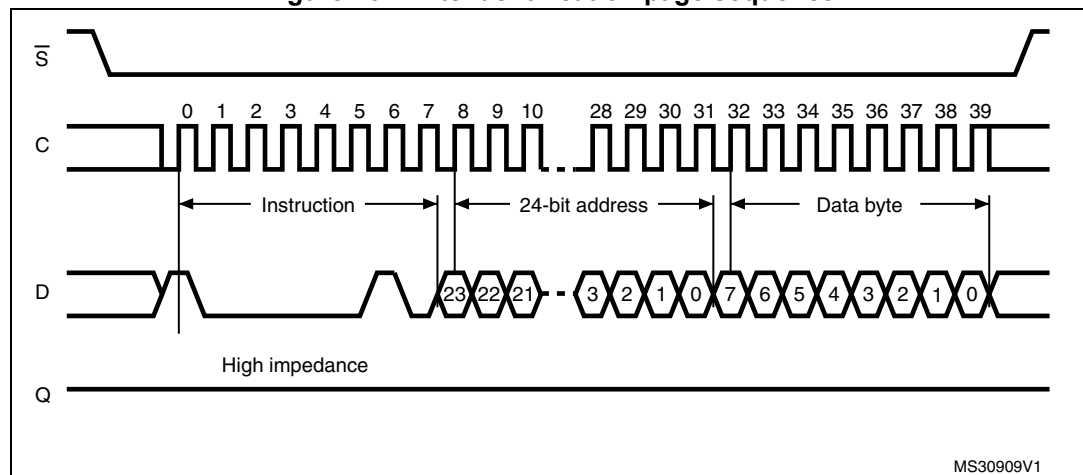


## 6.8 Write Identification Page (available only in M95256-D devices)

The Identification Page (64 bytes) is an additional page that can be written and (later) permanently locked in Read-only mode.

Writing this page is achieved with the Write Identification Page instruction (see [Table 3](#)). The Chip Select signal ( $\overline{S}$ ) is first driven low. The bits of the instruction byte, address bytes, and at least one data byte are then shifted in on Serial Data Input (D). Address bit A10 must be 0, upper address bits are Don't Care, the lower address bits [A5:A0] address bits define the byte address inside the identification page. The instruction sequence is shown in [Figure 16](#).

Figure 16. Write identification page sequence

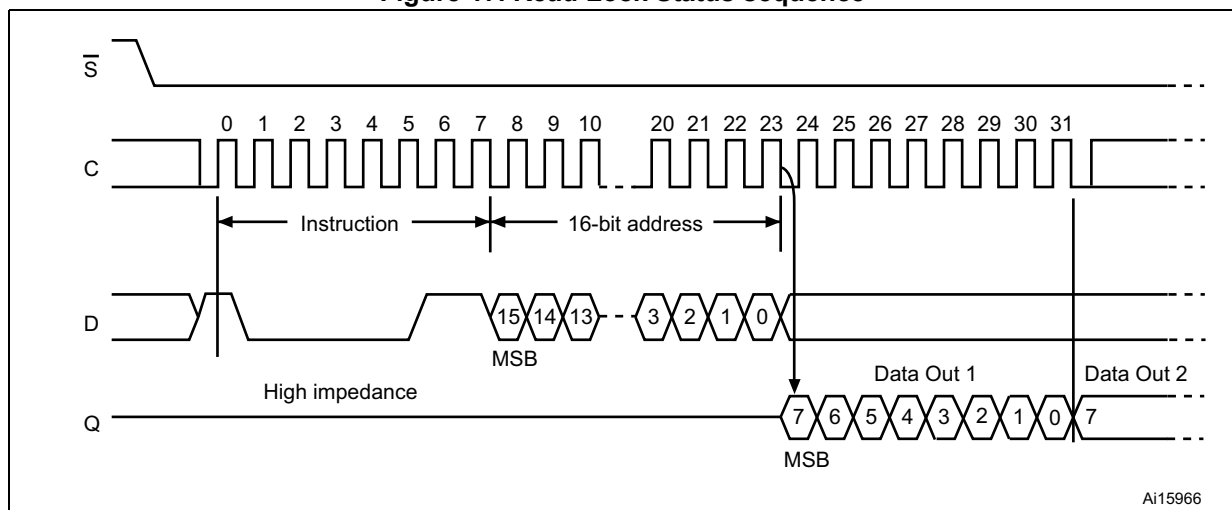


## 6.9 Read Lock Status (available only in M95256-D devices)

The Read Lock Status instruction (see [Table 3](#)) is used to check whether the Identification Page is locked or not in Read-only mode. The Read Lock Status sequence is defined with the Chip Select ( $\overline{S}$ ) first driven low. The bits of the instruction byte and address bytes are then shifted in on Serial Data Input (D). Address bit A10 must be 1, all other address bits are Don't Care. The Lock bit is the LSB (least significant bit) of the byte read on Serial Data Output (Q). It is at "1" when the lock is active and at "0" when the lock is not active. If Chip Select ( $\overline{S}$ ) continues to be driven low, the same data byte is shifted out. The read cycle is terminated by driving Chip Select ( $\overline{S}$ ) high.

The instruction sequence is shown in [Figure 17](#).

**Figure 17. Read Lock Status sequence**



## 6.10 Lock ID (available only in M95256-D devices)

The Lock ID instruction permanently locks the Identification Page in read-only mode. Before this instruction can be accepted, a Write Enable (WREN) instruction must have been executed.

The Lock ID instruction is issued by driving Chip Select ( $\overline{S}$ ) low, sending the instruction code, the address and a data byte on Serial Data Input (D), and driving Chip Select ( $\overline{S}$ ) high. In the address sent, A10 must be equal to 1, all other address bits are Don't Care. The data byte sent must be equal to the binary value xxxx xx1x, where x = Don't Care.

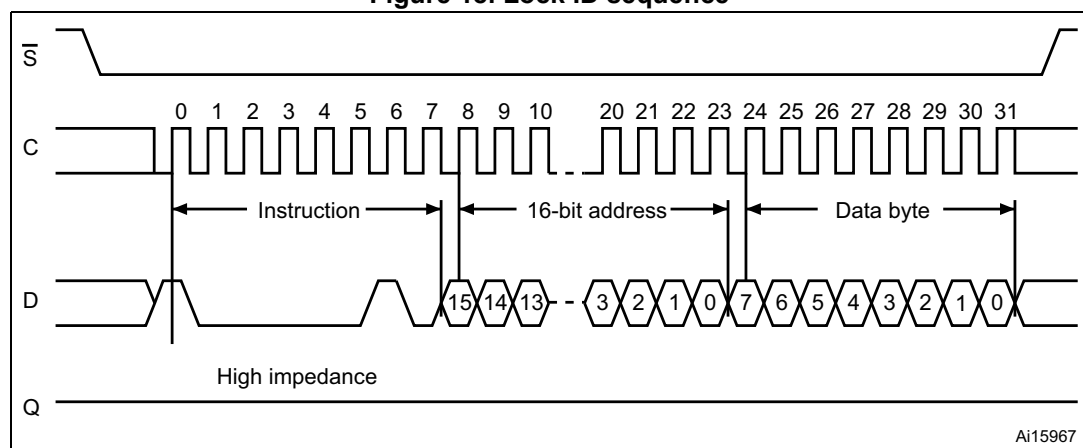
Chip Select ( $\overline{S}$ ) must be driven high after the rising edge of Serial Clock (C) that latches in the eighth bit of the data byte, and before the next rising edge of Serial Clock (C). Otherwise, the Lock ID instruction is not executed.

Driving Chip Select ( $\overline{S}$ ) high at a byte boundary of the input data triggers the self-timed write cycle whose duration is  $t_{W}$  (as specified in AC characteristics in [Section 9: DC and AC parameters](#)). The instruction sequence is shown in [Figure 18](#).

The instruction is discarded, and is not executed, under the following conditions:

- If a Write cycle is already in progress,
- If the Block Protect bits (BP1,BP0) = (1,1),
- If a rising edge on Chip Select ( $\overline{S}$ ) happens outside of a byte boundary.

**Figure 18. Lock ID sequence**



## 7 Power-up and delivery state

### 7.1 Power-up state

After power-up, the device is in the following state:

- Standby power mode,
- deselected (after power-up, a falling edge is required on Chip Select ( $\overline{S}$ ) before any instructions can be started),
- not in the Hold condition,
- the Write Enable Latch (WEL) is reset to 0,
- Write In Progress (WIP) is reset to 0.

The SRWD, BP1 and BP0 bits of the Status Register are unchanged from the previous power-down (they are non-volatile bits).

### 7.2 Initial delivery state

The device is delivered with the memory array bits and identification page bits set to all 1s (each byte = FFh). The Status Register Write Disable (SRWD) and Block Protect (BP1 and BP0) bits are initialized to 0.

## 8 Maximum ratings

Stressing the device outside the ratings listed in [Table 7](#) may cause permanent damage to the device. These are stress ratings only, and operation of the device at these, or any other conditions outside those indicated in the operating sections of this specification, is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Table 7. Absolute maximum ratings**

| Symbol            | Parameter                                                         | Min.                    | Max.                 | Unit |
|-------------------|-------------------------------------------------------------------|-------------------------|----------------------|------|
|                   | Ambient operating temperature                                     | −40                     | 130                  | °C   |
| T <sub>STG</sub>  | Storage temperature                                               | −65                     | 150                  | °C   |
| T <sub>LEAD</sub> | Lead temperature during soldering                                 | See note <sup>(1)</sup> |                      | °C   |
| V <sub>O</sub>    | Output voltage                                                    | −0.50                   | V <sub>CC</sub> +0.6 | V    |
| V <sub>I</sub>    | Input voltage                                                     | −0.50                   | 6.5                  | V    |
| V <sub>CC</sub>   | Supply voltage                                                    | −0.50                   | 6.5                  | V    |
| I <sub>OL</sub>   | DC output current (Q = 0)                                         | −                       | 5                    | mA   |
| I <sub>OH</sub>   | DC output current (Q = 1)                                         | −                       | 5                    | mA   |
| V <sub>ESD</sub>  | Electrostatic discharge voltage (human body model) <sup>(2)</sup> | −                       | 4000 <sup>(3)</sup>  | V    |

1. Compliant with JEDEC standard J-STD-020D (for small-body, Sn-Pb or Pb free assembly), the ST ECOPACK<sup>®</sup> 7191395 specification, and the European directive on Restrictions on Hazardous Substances (RoHS directive 2011/65/EU of July 2011).
2. Positive and negative pulses applied on different combinations of pin connections, according to AEC-Q100-002 (compliant with ANSI/ESDA/JEDEC JS-001-2012, C1=100 pF, R1=1500 Ω, R2=500 Ω).
3. V<sub>ESD</sub> is 3000 V (max) for the M95256 identified by process letters KA.

## 9 DC and AC parameters

This section summarizes the operating conditions and the DC/AC characteristics of the devices.

**Table 8. Operating conditions (M95256-W, device grade 6)**

| Symbol   | Parameter                     | Min. | Max. | Unit |
|----------|-------------------------------|------|------|------|
| $V_{CC}$ | Supply voltage                | 2.5  | 5.5  | V    |
| $T_A$    | Ambient operating temperature | -40  | 85   | °C   |

**Table 9. Operating conditions (M95256-R, device grade 6)**

| Symbol   | Parameter                     | Min. | Max. | Unit |
|----------|-------------------------------|------|------|------|
| $V_{CC}$ | Supply voltage                | 1.8  | 5.5  | V    |
| $T_A$    | Ambient operating temperature | -40  | 85   | °C   |

**Table 10. Operating conditions (M95256-DF, device grade 6)**

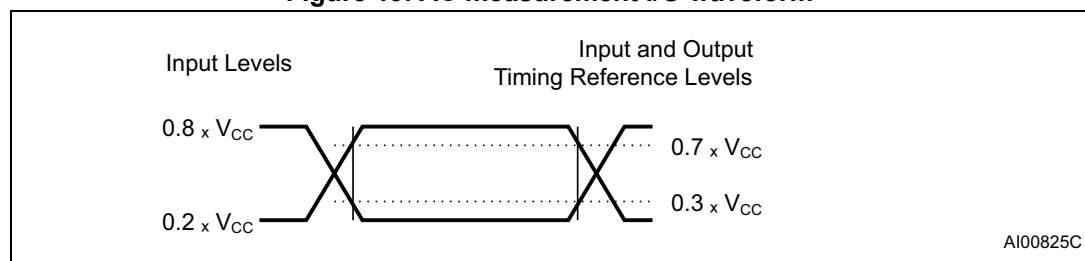
| Symbol   | Parameter                     | Min. | Max. | Unit |
|----------|-------------------------------|------|------|------|
| $V_{CC}$ | Supply voltage                | 1.7  | 5.5  | V    |
| $T_A$    | Ambient operating temperature | -40  | 85   | °C   |

**Table 11. AC measurement conditions**

| Symbol | Parameter                                  | Min.                         | Max.                     | Unit |
|--------|--------------------------------------------|------------------------------|--------------------------|------|
| $C_L$  | Load capacitance                           | -                            | 30 or 100 <sup>(1)</sup> | pF   |
| -      | Input rise and fall times                  | -                            | 25                       | ns   |
| -      | Input pulse voltages                       | 0.2 $V_{CC}$ to 0.8 $V_{CC}$ |                          | V    |
| -      | Input and output timing reference voltages | 0.3 $V_{CC}$ to 0.7 $V_{CC}$ |                          | V    |

1. 100 pF when the clock frequency  $f_C$  is lower than 10 MHz, 30 pF when the clock frequency  $f_C$  is equal to or greater than 10 MHz.

**Figure 19. AC measurement I/O waveform**





**Table 12. Cycling performance by groups of four bytes**

| Symbol | Parameter <sup>(1)</sup>             | Test conditions                                                                   | Min. | Max.      | Unit                       |
|--------|--------------------------------------|-----------------------------------------------------------------------------------|------|-----------|----------------------------|
| Ncycle | Write cycle endurance <sup>(2)</sup> | $T_A \leq 25\text{ }^{\circ}\text{C}$ ,<br>$V_{CC(\min)} < V_{CC} < V_{CC(\max)}$ | -    | 4,000,000 | Write cycle <sup>(3)</sup> |
|        |                                      | $T_A = 85\text{ }^{\circ}\text{C}$ ,<br>$V_{CC(\min)} < V_{CC} < V_{CC(\max)}$    | -    | 1,200,000 |                            |

1. Cycling performance for products identified by process letters K B
2. The Write cycle endurance is defined for groups of four data bytes located at addresses  $[4*N, 4*N+1, 4*N+2, 4*N+3]$  where N is an integer. The Write cycle endurance is defined by characterization and qualification.
3. A Write cycle is executed when either a Page Write, a Byte Write, a WRSR, a WRID or an LID instruction is decoded. When using the Byte Write, the Page Write or the WRID instruction, refer also to [Section 6.6.1: Cycling with Error Correction Code \(ECC\)](#).

**Table 13. Memory cell data retention**

| Parameter                     | Test conditions                    | Min. | Unit |
|-------------------------------|------------------------------------|------|------|
| Data retention <sup>(1)</sup> | $T_A = 55\text{ }^{\circ}\text{C}$ | 200  | Year |

1. For products identified by process letters KB. The data retention behavior is checked in production, while the 200-year limit is defined from characterization and qualification results.

**Table 14. Capacitance**

| Symbol    | Parameter                      | Test conditions <sup>(1)</sup> | Min. | Max. | Unit |
|-----------|--------------------------------|--------------------------------|------|------|------|
| $C_{OUT}$ | Output capacitance (Q)         | $V_{OUT} = 0\text{ V}$         | -    | 8    | pF   |
| $C_{IN}$  | Input capacitance (D)          | $V_{IN} = 0\text{ V}$          | -    | 8    | pF   |
|           | Input capacitance (other pins) | $V_{IN} = 0\text{ V}$          | -    | 6    | pF   |

1. Sampled only, not 100% tested, at  $T_A = 25\text{ }^{\circ}\text{C}$  and a frequency of 5 MHz.

Table 15. DC characteristics (M95256-W, device grade 6)

| Symbol                   | Parameter                | Test conditions                                                                | Min.         | Max.                 | Unit    |
|--------------------------|--------------------------|--------------------------------------------------------------------------------|--------------|----------------------|---------|
| $I_{LI}$                 | Input leakage current    | $V_{IN} = V_{SS}$ or $V_{CC}$                                                  | -            | $\pm 2$              | $\mu A$ |
| $I_{LO}$                 | Output leakage current   | $\overline{S} = V_{CC}$ , $V_{OUT} = V_{SS}$ or $V_{CC}$                       | -            | $\pm 2$              | $\mu A$ |
| $I_{CC}$                 | Supply current (Read)    | $V_{CC} = 2.5 V$ , $C = 0.1 V_{CC} / 0.9 V_{CC}$ at 5 MHz, $Q = \text{open}$   | -            | 3 <sup>(1)</sup>     | mA      |
|                          |                          | $V_{CC} = 2.5 V$ , $C = 0.1 V_{CC} / 0.9 V_{CC}$ at 10 MHz, $Q = \text{open}$  | -            | 2 <sup>(2)</sup>     |         |
|                          |                          | $V_{CC} = 5.5 V$ , $C = 0.1 V_{CC} / 0.9 V_{CC}$ at 5 MHz, $Q = \text{open}$   | -            | 5 <sup>(1)</sup>     |         |
|                          |                          | $V_{CC} = 5.5 V$ , $C = 0.1 V_{CC} / 0.9 V_{CC}$ at 20 MHz, $Q = \text{open}$  | -            | 5 <sup>(3)</sup>     |         |
| $I_{CC0}$ <sup>(4)</sup> | Supply current (Write)   | During $t_W$ , $\overline{S} = V_{CC}$ , $2.5 V < V_{CC} < 5.5 V$              | -            | 5                    | mA      |
| $I_{CC1}$                | Supply current (Standby) | $\overline{S} = V_{CC}$ , $V_{CC} = 5.5 V$ , $V_{IN} = V_{SS}$ or $V_{CC}$ ,   | -            | 3 <sup>(5)</sup> (6) | $\mu A$ |
|                          |                          | $\overline{S} = V_{CC}$ , $V_{CC} = 2.5 V$ , $V_{IN} = V_{SS}$ or $V_{CC}$ ,   | -            | 2 <sup>(5)</sup>     |         |
| $V_{IL}$                 | Input low voltage        | -                                                                              | -0.45        | $0.3 V_{CC}$         | V       |
| $V_{IH}$                 | Input high voltage       | -                                                                              | $0.7 V_{CC}$ | $V_{CC}+1$           | V       |
| $V_{OL}$                 | Output low voltage       | $V_{CC} = 2.5 V$ and $I_{OL} = 1.5 mA$ or $V_{CC} = 5 V$ and $I_{OL} = 2 mA$   | -            | 0.4                  | V       |
| $V_{OH}$                 | Output high voltage      | $V_{CC} = 2.5 V$ and $I_{OH} = -0.4 mA$ or $V_{CC} = 5 V$ and $I_{OH} = -2 mA$ | $0.8 V_{CC}$ | -                    | V       |

1. For previous products identified with process letter A.
2. 4 mA at 10 MHz and 3 mA at 5 MHz for M95256 previous devices identified by process letter A.
3. For the M95256 devices identified by process letter K.
4. Characterized only, not tested in production.
5. 5  $\mu A$  for previous M95256 devices identified by process letter A.
6. 2  $\mu A$  for the devices identified by process letter G or S.

Table 16. DC characteristics (M95256-R, device grade 6)

| Symbol          | Parameter                | Test conditions <sup>(1)</sup>                                             | Min.          | Max.             | Unit    |
|-----------------|--------------------------|----------------------------------------------------------------------------|---------------|------------------|---------|
| $I_{LI}$        | Input leakage current    | $V_{IN} = V_{SS}$ or $V_{CC}$                                              | -             | $\pm 2$          | $\mu A$ |
| $I_{LO}$        | Output leakage current   | $\overline{S} = V_{CC}$ , voltage applied on Q = $V_{SS}$ or $V_{CC}$      | -             | $\pm 2$          | $\mu A$ |
| $I_{CC}$        | Supply current (Read)    | $V_{CC} = 1.8 V$ , $C = 0.1 V_{CC}$ or $0.9 V_{CC}$ , at 2 MHz, Q = open   | -             | 1 <sup>(2)</sup> | mA      |
|                 |                          | $V_{CC} = 1.8 V$ , $C = 0.1 V_{CC}$ or $0.9 V_{CC}$ , at 5 MHz, Q = open   | -             | 2 <sup>(3)</sup> |         |
| $I_{CC0}^{(4)}$ | Supply current (Write)   | $V_{CC} = 1.8 V$ , during $t_W$ , $\overline{S} = V_{CC}$                  | -             | 3                | mA      |
| $I_{CC1}$       | Supply current (Standby) | $V_{CC} = 1.8 V$ , $\overline{S} = V_{CC}$ , $V_{IN} = V_{SS}$ or $V_{CC}$ | -             | 1 <sup>(5)</sup> | $\mu A$ |
| $V_{IL}$        | Input low voltage        | $1.8 V \leq V_{CC} < 2.5 V$                                                | -0.45         | $0.25 V_{CC}$    | V       |
| $V_{IH}$        | Input high voltage       | $1.8 V \leq V_{CC} < 2.5 V$                                                | $0.75 V_{CC}$ | $V_{CC}+1$       | V       |
| $V_{OL}$        | Output low voltage       | $I_{OL} = 0.15 mA$ , $V_{CC} = 1.8 V$                                      | -             | 0.3              | V       |
| $V_{OH}$        | Output high voltage      | $I_{OH} = -0.1 mA$ , $V_{CC} = 1.8 V$                                      | $0.8 V_{CC}$  | -                | V       |

1. If the application uses the M95256-R device at  $2.5 V < V_{CC} < 5.5 V$  and  $-40^\circ C < T_A < +85^\circ C$ , refer to [Table 15: DC characteristics \(M95256-W, device grade 6\)](#), rather than to the above table.
2. Value tested only for previous M95256 devices identified by process letter A.
3. Only for M95256 devices identified by process letter K.
4. Characterized only, not tested in production.
5. 3  $\mu A$  for previous M95256 devices identified by process letter A.

Table 17. DC characteristics (M95256-DF, device grade 6)

| Symbol          | Parameter                | Test conditions <sup>(1)</sup>                                             | Min.          | Max.          | Unit    |
|-----------------|--------------------------|----------------------------------------------------------------------------|---------------|---------------|---------|
| $I_{LI}$        | Input leakage current    | $V_{IN} = V_{SS}$ or $V_{CC}$                                              | -             | $\pm 2$       | $\mu A$ |
| $I_{LO}$        | Output leakage current   | $\overline{S} = V_{CC}$ , voltage applied on Q = $V_{SS}$ or $V_{CC}$      | -             | $\pm 2$       | $\mu A$ |
| $I_{CC}$        | Supply current (Read)    | $V_{CC} = 1.7 V$ , C = 0.1 $V_{CC}$ or 0.9 $V_{CC}$ , at 5 MHz, Q = open   | -             | 2             | mA      |
| $I_{CC0}^{(2)}$ | Supply current (Write)   | $V_{CC} = 1.7 V$ , during $t_W$ , $\overline{S} = V_{CC}$                  | -             | 3             | mA      |
| $I_{CC1}$       | Supply current (Standby) | $V_{CC} = 1.7 V$ , $\overline{S} = V_{CC}$ , $V_{IN} = V_{SS}$ or $V_{CC}$ | -             | 1             | $\mu A$ |
| $V_{IL}$        | Input low voltage        | $1.7 V \leq V_{CC} < 2.5 V$                                                | -0.45         | $0.25 V_{CC}$ | V       |
| $V_{IH}$        | Input high voltage       | $1.7 V \leq V_{CC} < 2.5 V$                                                | $0.75 V_{CC}$ | $V_{CC}+1$    | V       |
| $V_{OL}$        | Output low voltage       | $I_{OL} = 0.15 mA$ , $V_{CC} = 1.7 V$                                      | -             | 0.3           | V       |
| $V_{OH}$        | Output high voltage      | $I_{OH} = -0.1 mA$ , $V_{CC} = 1.7 V$                                      | $0.8 V_{CC}$  | -             | V       |

1. If the application uses the M95256-DF devices at  $2.5 V \leq V_{CC} \leq 5.5 V$  and  $-40 ^\circ C \leq T_A \leq +85 ^\circ C$ , please refer to [Table 15: DC characteristics \(M95256-W, device grade 6\)](#), rather than to the above table.
2. Characterized only, not tested in production.

Table 18. AC characteristics (M95256-W, device grade 6)

| Test conditions specified in<br><i>Table 8</i> and <i>Table 11</i> |                   |                                             | Previous <sup>(1)</sup><br>and new<br>products<br><br>C <sub>L</sub> = 100 pF |      | New products <sup>(2)</sup><br>C <sub>L</sub> = 30 pF |      |                        |      | Unit |
|--------------------------------------------------------------------|-------------------|---------------------------------------------|-------------------------------------------------------------------------------|------|-------------------------------------------------------|------|------------------------|------|------|
|                                                                    |                   |                                             |                                                                               |      | V <sub>CC</sub> ≥ 2.5V                                |      | V <sub>CC</sub> ≥ 4.5V |      |      |
|                                                                    |                   |                                             | Symbol                                                                        | Alt. | Parameter                                             | Min. | Max.                   | Min. |      |
| f <sub>C</sub>                                                     | f <sub>SCK</sub>  | Clock frequency                             | DC                                                                            | 5    | DC                                                    | 10   | DC                     | 20   | MHz  |
| t <sub>SLCH</sub>                                                  | t <sub>CSS1</sub> | $\overline{S}$ active setup time            | 90                                                                            | -    | 30                                                    | -    | 15                     | -    | ns   |
| t <sub>SHCH</sub>                                                  | t <sub>CSS2</sub> | $\overline{S}$ not active setup time        | 90                                                                            | -    | 30                                                    | -    | 15                     | -    | ns   |
| t <sub>SHSL</sub>                                                  | t <sub>CS</sub>   | $\overline{S}$ deselect time                | 100                                                                           | -    | 40                                                    | -    | 20                     | -    | ns   |
| t <sub>CHSH</sub>                                                  | t <sub>CSH</sub>  | $\overline{S}$ active hold time             | 90                                                                            | -    | 30                                                    | -    | 15                     | -    | ns   |
| t <sub>CHSL</sub>                                                  | -                 | $\overline{S}$ not active hold time         | 90                                                                            | -    | 30                                                    | -    | 15                     | -    | ns   |
| t <sub>CH</sub> <sup>(3)</sup>                                     | t <sub>CLH</sub>  | Clock high time                             | 90                                                                            | -    | 40                                                    | -    | 20                     | -    | ns   |
| t <sub>CL</sub> <sup>(3)</sup>                                     | t <sub>CLL</sub>  | Clock low time                              | 90                                                                            | -    | 40                                                    | -    | 20                     | -    | ns   |
| t <sub>CLCH</sub> <sup>(3)</sup>                                   | t <sub>RC</sub>   | Clock rise time                             | -                                                                             | 1    | -                                                     | 2    | -                      | 2    | μs   |
| t <sub>CHCL</sub> <sup>(3)</sup>                                   | t <sub>FC</sub>   | Clock fall time                             | -                                                                             | 1    | -                                                     | 2    | -                      | 2    | μs   |
| t <sub>DVCH</sub>                                                  | t <sub>DSU</sub>  | Data in setup time                          | 20                                                                            | -    | 10                                                    | -    | 5                      | -    | ns   |
| t <sub>CHDX</sub>                                                  | t <sub>DH</sub>   | Data in hold time                           | 30                                                                            | -    | 10                                                    | -    | 10                     | -    | ns   |
| t <sub>HHCH</sub>                                                  | -                 | Clock low hold time after HOLD not active   | 70                                                                            | -    | 30                                                    | -    | 15                     | -    | ns   |
| t <sub>HLCH</sub>                                                  | -                 | Clock low hold time after HOLD active       | 40                                                                            | -    | 30                                                    | -    | 15                     | -    | ns   |
| t <sub>CLHL</sub>                                                  | -                 | Clock low setup time before HOLD active     | 0                                                                             | -    | 0                                                     | -    | 0                      | -    | ns   |
| t <sub>CLHH</sub>                                                  | -                 | Clock low setup time before HOLD not active | 0                                                                             | -    | 0                                                     | -    | 0                      | -    | ns   |
| t <sub>SHQZ</sub> <sup>(4)</sup>                                   | t <sub>DIS</sub>  | Output disable time                         | -                                                                             | 100  | -                                                     | 40   | -                      | 20   | ns   |
| t <sub>CLQV</sub>                                                  | t <sub>V</sub>    | Clock low to output valid                   | -                                                                             | 60   | -                                                     | 40   | -                      | 20   | ns   |
| t <sub>CLQX</sub>                                                  | t <sub>HO</sub>   | Output hold time                            | 0                                                                             | -    | 0                                                     | -    | 0                      | -    | ns   |
| t <sub>QLQH</sub> <sup>(4)</sup>                                   | t <sub>RO</sub>   | Output rise time                            | -                                                                             | 50   | -                                                     | 20   | -                      | 10   | ns   |
| t <sub>QHQL</sub> <sup>(4)</sup>                                   | t <sub>FO</sub>   | Output fall time                            | -                                                                             | 50   | -                                                     | 20   | -                      | 10   | ns   |
| t <sub>HHQV</sub>                                                  | t <sub>LZ</sub>   | HOLD high to output valid                   | -                                                                             | 50   | -                                                     | 40   | -                      | 20   | ns   |
| t <sub>HLQZ</sub> <sup>(4)</sup>                                   | t <sub>HZ</sub>   | HOLD low to output High-Z                   | -                                                                             | 100  | -                                                     | 40   | -                      | 20   | ns   |
| t <sub>W</sub>                                                     | t <sub>WC</sub>   | Write time                                  | -                                                                             | 5    | -                                                     | 5    | -                      | 5    | ms   |

1. Previous products are identified by process letters AB.
2. New products are M95256 devices identified by process letter K.
3.  $t_{CH} + t_{CL}$  must never be less than the shortest possible clock period,  $1 / f_C(\text{max})$ .
4. Characterized only, not tested in production.

Table 19. AC characteristics (M95256-R, device grade 6)

| Test conditions specified in <i>Table 9</i> and <i>Table 11</i> |                   |                                                          |                                  |      |                             |      |                        |      |                        |      |      |
|-----------------------------------------------------------------|-------------------|----------------------------------------------------------|----------------------------------|------|-----------------------------|------|------------------------|------|------------------------|------|------|
| Symbol                                                          | Alt.              | Parameter                                                | Previous products <sup>(1)</sup> |      | New products <sup>(2)</sup> |      |                        |      |                        |      | Unit |
|                                                                 |                   |                                                          |                                  |      | V <sub>CC</sub> ≥ 1.8V      |      | V <sub>CC</sub> ≥ 2.5V |      | V <sub>CC</sub> ≥ 4.5V |      |      |
|                                                                 |                   |                                                          | Min.                             | Max. | Min.                        | Max. | Min.                   | Max. | Min.                   | Max. |      |
| f <sub>C</sub>                                                  | f <sub>SCK</sub>  | Clock frequency                                          | -                                | 2    | -                           | 5    | -                      | 10   | -                      | 20   | MHz  |
| t <sub>SLCH</sub>                                               | t <sub>CSS1</sub> | $\overline{S}$ active setup time                         | 200                              | -    | 60                          | -    | 30                     | -    | 15                     | -    | ns   |
| t <sub>SHCH</sub>                                               | t <sub>CSS2</sub> | $\overline{S}$ not active setup time                     | 200                              | -    | 60                          | -    | 30                     | -    | 15                     | -    | ns   |
| t <sub>SHSL</sub>                                               | t <sub>CS</sub>   | $\overline{S}$ deselect time                             | 200                              | -    | 90                          | -    | 40                     | -    | 20                     | -    | ns   |
| t <sub>CHSH</sub>                                               | t <sub>CSH</sub>  | $\overline{S}$ active hold time                          | 200                              | -    | 60                          | -    | 30                     | -    | 15                     | -    | ns   |
| t <sub>CHSL</sub>                                               | -                 | $\overline{S}$ not active hold time                      | 200                              | -    | 60                          | -    | 30                     | -    | 15                     | -    | ns   |
| t <sub>CH</sub> <sup>(3)</sup>                                  | t <sub>CLH</sub>  | Clock high time                                          | 200                              | -    | 80                          | -    | 40                     | -    | 20                     | -    | ns   |
| t <sub>CL</sub> <sup>(3)</sup>                                  | t <sub>CLL</sub>  | Clock low time                                           | 200                              | -    | 80                          | -    | 40                     | -    | 20                     | -    | ns   |
| t <sub>CLCH</sub> <sup>(4)</sup>                                | t <sub>RC</sub>   | Clock rise time                                          | -                                | 1    | -                           | 2    | -                      | 2    | -                      | 2    | μs   |
| t <sub>CHCL</sub> <sup>(4)</sup>                                | t <sub>FC</sub>   | Clock fall time                                          | -                                | 1    | -                           | 2    | -                      | 2    | -                      | 2    | μs   |
| t <sub>DVCH</sub>                                               | t <sub>DSU</sub>  | Data in setup time                                       | 40                               | -    | 20                          | -    | 10                     | -    | 5                      | -    | ns   |
| t <sub>CHDX</sub>                                               | t <sub>DH</sub>   | Data in hold time                                        | 50                               | -    | 20                          | -    | 10                     | -    | 10                     | -    | ns   |
| t <sub>HHCH</sub>                                               | -                 | Clock low hold time after $\overline{HOLD}$ not active   | 140                              | -    | 60                          | -    | 30                     | -    | 15                     | -    | ns   |
| t <sub>HLCH</sub>                                               | -                 | Clock low hold time after $\overline{HOLD}$ active       | 90                               | -    | 60                          | -    | 30                     | -    | 15                     | -    | ns   |
| t <sub>CLHL</sub>                                               | -                 | Clock low setup time before $\overline{HOLD}$ active     | 0                                | -    | 0                           | -    | 0                      | -    | 0                      | -    | ns   |
| t <sub>CLHH</sub>                                               | -                 | Clock low setup time before $\overline{HOLD}$ not active | 0                                | -    | 0                           | -    | 0                      | -    | 0                      | -    | ns   |
| t <sub>SHQZ</sub> <sup>(4)</sup>                                | t <sub>DIS</sub>  | Output disable time                                      | -                                | 250  | -                           | 80   | -                      | 40   | -                      | 20   | ns   |
| t <sub>CLQV</sub>                                               | t <sub>V</sub>    | Clock low to output valid                                | -                                | 150  | -                           | 80   | -                      | 40   | -                      | 20   | ns   |
| t <sub>CLQX</sub>                                               | t <sub>HO</sub>   | Output hold time                                         | 0                                | -    | 0                           | -    | -                      | -    | -                      | -    | ns   |
| t <sub>QLQH</sub> <sup>(4)</sup>                                | t <sub>RO</sub>   | Output rise time                                         | -                                | 100  | -                           | 20   | -                      | 20   | -                      | 10   | ns   |
| t <sub>QHQL</sub> <sup>(4)</sup>                                | t <sub>FO</sub>   | Output fall time                                         | -                                | 100  | -                           | 20   | -                      | 20   | -                      | 10   | ns   |
| t <sub>HHQV</sub>                                               | t <sub>LZ</sub>   | $\overline{HOLD}$ high to output valid                   | -                                | 100  | -                           | 80   | -                      | 40   | -                      | 20   | ns   |
| t <sub>HLQZ</sub> <sup>(4)</sup>                                | t <sub>HZ</sub>   | $\overline{HOLD}$ low to output High-Z                   | -                                | 250  | -                           | 80   | -                      | 40   | -                      | 20   | ns   |
| t <sub>W</sub>                                                  | t <sub>WC</sub>   | Write time                                               | -                                | 5    | -                           | 5    | -                      | 5    | -                      | 5    | ms   |

1. Previous products are identified by process letters AB.

2. New products are the M95256 devices identified by process letter K.

3.  $t_{CH} + t_{CL}$  must never be less than the shortest possible clock period,  $1 / f_C(\max)$ .

4. Characterized only, not tested in production.

Table 20. AC characteristics (M95256-DF, device grade 6)

| Test conditions specified in <a href="#">Table 10</a> and <a href="#">Table 11</a> |            |                                                          |                            |      |                            |      |                            |      |               |
|------------------------------------------------------------------------------------|------------|----------------------------------------------------------|----------------------------|------|----------------------------|------|----------------------------|------|---------------|
| Symbol                                                                             | Alt.       | Parameter                                                | $V_{CC} \geq 1.7\text{ V}$ |      | $V_{CC} \geq 2.5\text{ V}$ |      | $V_{CC} \geq 4.5\text{ V}$ |      | Unit          |
|                                                                                    |            |                                                          | Min.                       | Max. | Min.                       | Max. | Min.                       | Max. |               |
| $f_C$                                                                              | $f_{SCK}$  | Clock frequency                                          | -                          | 5    | -                          | 10   | -                          | 20   | MHz           |
| $t_{SLCH}$                                                                         | $t_{CSS1}$ | $\overline{S}$ active setup time                         | 60                         | -    | 30                         | -    | 15                         | -    | ns            |
| $t_{SHCH}$                                                                         | $t_{CSS2}$ | $\overline{S}$ not active setup time                     | 60                         | -    | 30                         | -    | 15                         | -    | ns            |
| $t_{SHSL}$                                                                         | $t_{CS}$   | $\overline{S}$ deselect time                             | 90                         | -    | 40                         | -    | 20                         | -    | ns            |
| $t_{CHSH}$                                                                         | $t_{CSH}$  | $\overline{S}$ active hold time                          | 60                         | -    | 30                         | -    | 15                         | -    | ns            |
| $t_{CHSL}$                                                                         | -          | $\overline{S}$ not active hold time                      | 60                         | -    | 30                         | -    | 15                         | -    | ns            |
| $t_{CH}^{(1)}$                                                                     | $t_{CLH}$  | Clock high time                                          | 80                         | -    | 40                         | -    | 20                         | -    | ns            |
| $t_{CL}^{(2)}$                                                                     | $t_{CLL}$  | Clock low time                                           | 80                         | -    | 40                         | -    | 20                         | -    | ns            |
| $t_{CLCH}^{(2)}$                                                                   | $t_{RC}$   | Clock rise time                                          | -                          | 2    | -                          | 2    | -                          | 2    | $\mu\text{s}$ |
| $t_{CHCL}$                                                                         | $t_{FC}$   | Clock fall time                                          | -                          | 2    | -                          | 2    | -                          | 2    | $\mu\text{s}$ |
| $t_{DVCH}$                                                                         | $t_{DSU}$  | Data in setup time                                       | 20                         | -    | 10                         | -    | 5                          | -    | ns            |
| $t_{CHDX}$                                                                         | $t_{DH}$   | Data in hold time                                        | 20                         | -    | 10                         | -    | 10                         | -    | ns            |
| $t_{HHCH}$                                                                         | -          | Clock low hold time after $\overline{HOLD}$ not active   | 60                         | -    | 30                         | -    | 15                         | -    | ns            |
| $t_{HLCH}$                                                                         | -          | Clock low hold time after $\overline{HOLD}$ active       | 60                         | -    | 30                         | -    | 15                         | -    | ns            |
| $t_{CLHL}$                                                                         | -          | Clock low setup time before $\overline{HOLD}$ active     | 0                          | -    | 0                          | -    | 0                          | -    | ns            |
| $t_{CLHH}$                                                                         | -          | Clock low setup time before $\overline{HOLD}$ not active | 0                          | -    | 0                          | -    | 0                          | -    | ns            |
| $t_{SHQZ}$                                                                         | $t_{DIS}$  | Output disable time                                      | -                          | 80   | -                          | 40   | -                          | 20   | ns            |
| $t_{CLQV}$                                                                         | $t_V$      | Clock low to output valid                                | -                          | 80   | -                          | 40   | -                          | 20   | ns            |
| $t_{CLQX}$                                                                         | $t_{HO}$   | Output hold time                                         | 0                          | -    | 0                          | -    | 0                          | -    | ns            |
| $t_{QLQH}$                                                                         | $t_{RO}$   | Output rise time                                         | -                          | 20   | -                          | 20   | -                          | 10   | ns            |
| $t_{QHQL}$                                                                         | $t_{FO}$   | Output fall time                                         | -                          | 20   | -                          | 20   | -                          | 10   | ns            |
| $t_{HHQV}$                                                                         | $t_{LZ}$   | $\overline{HOLD}$ high to output valid                   | -                          | 80   | -                          | 40   | -                          | 20   | ns            |
| $t_{HLQZ}$                                                                         | $t_{HZ}$   | $\overline{HOLD}$ low to output High-Z                   | -                          | 80   | -                          | 40   | -                          | 20   | ns            |
| $t_W$                                                                              | $t_{WC}$   | Write time                                               | -                          | 5    | -                          | 5    | -                          | 5    | ms            |

- $t_{CH} + t_{CL}$  must never be less than the shortest possible clock period,  $1 / f_C(\text{max})$ .
- Characterized only, not tested in production.

Figure 20. Serial input timing

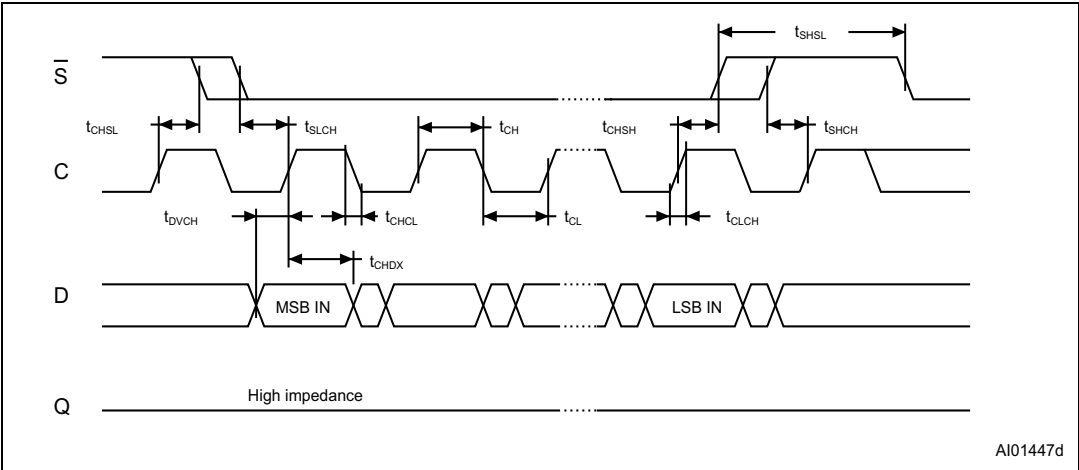


Figure 21. Hold timing

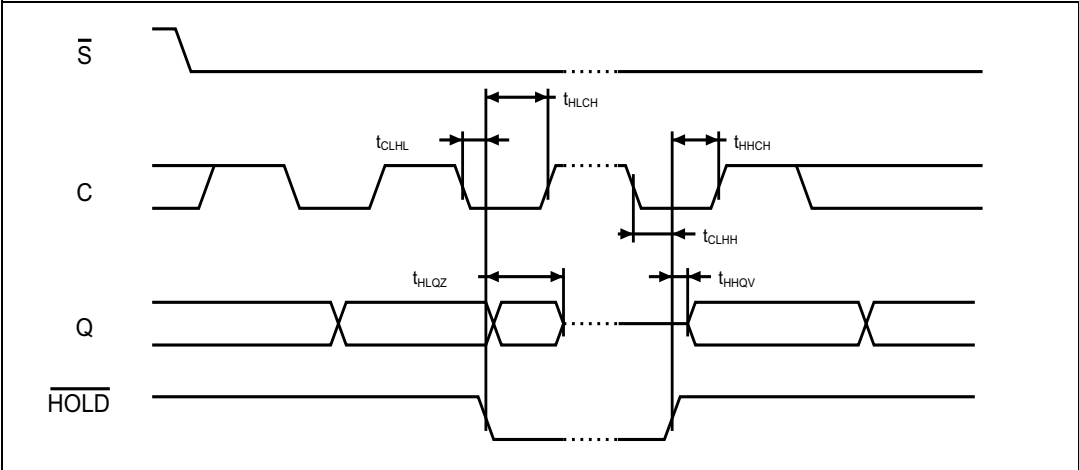
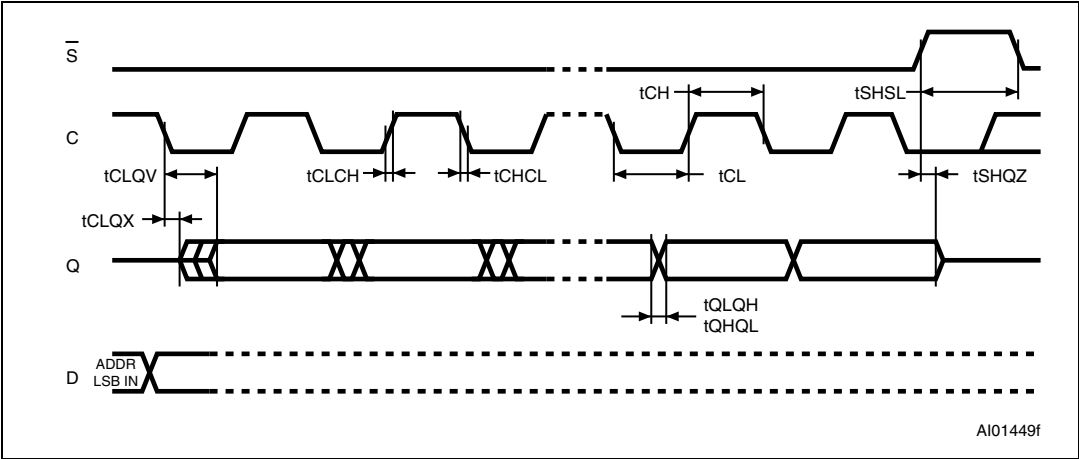


Figure 22. Serial output timing



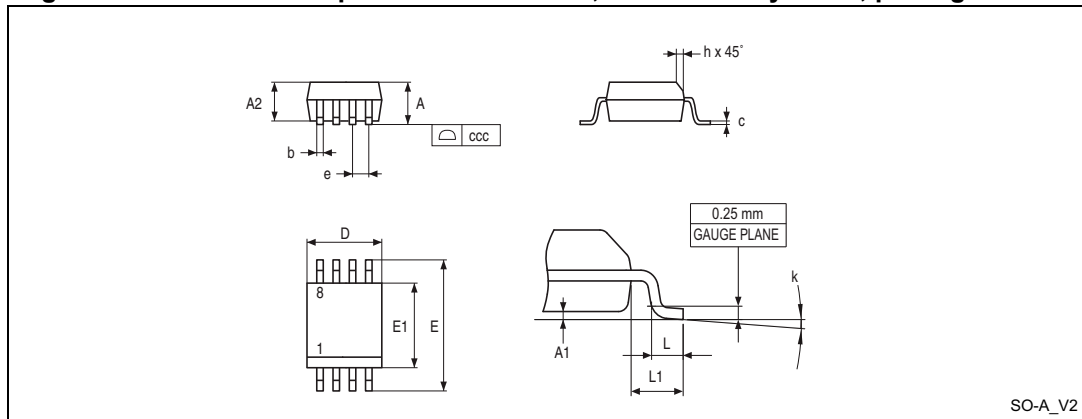


## 10 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 10.1 SO8N package information

Figure 23. SO8N – 8-lead plastic small outline, 150 mils body width, package outline



1. Drawing is not to scale.

Table 21. SO8N – 8-lead plastic small outline, 150 mils body width, package mechanical data

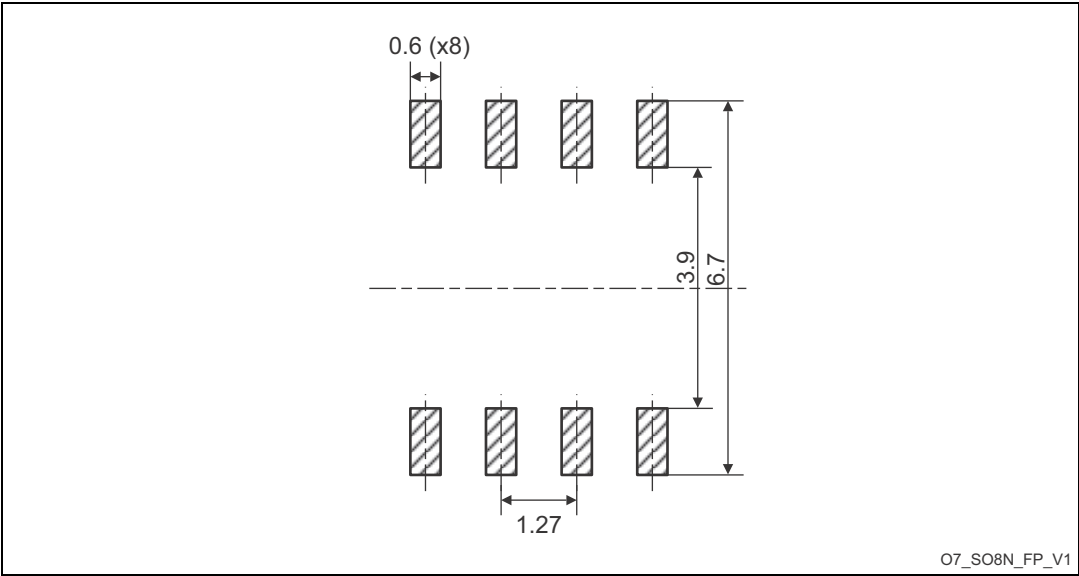
| Symbol | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|--------|-------------|-------|-------|-----------------------|--------|--------|
|        | Min.        | Typ.  | Max.  | Min.                  | Typ.   | Max.   |
| A      | -           | -     | 1.750 | -                     | -      | 0.0689 |
| A1     | 0.100       | -     | 0.250 | 0.0039                | -      | 0.0098 |
| A2     | 1.250       | -     | -     | 0.0492                | -      | -      |
| b      | 0.280       | -     | 0.480 | 0.0110                | -      | 0.0189 |
| c      | 0.170       | -     | 0.230 | 0.0067                | -      | 0.0091 |
| D      | 4.800       | 4.900 | 5.000 | 0.1890                | 0.1929 | 0.1969 |
| E      | 5.800       | 6.000 | 6.200 | 0.2283                | 0.2362 | 0.2441 |
| E1     | 3.800       | 3.900 | 4.000 | 0.1496                | 0.1535 | 0.1575 |
| e      | -           | 1.270 | -     | -                     | 0.0500 | -      |
| h      | 0.250       | -     | 0.500 | 0.0098                | -      | 0.0197 |
| k      | 0°          | -     | 8°    | 0°                    | -      | 8°     |
| L      | 0.400       | -     | 1.270 | 0.0157                | -      | 0.0500 |

Table 21. SO8N – 8-lead plastic small outline, 150 mils body width, package mechanical data (continued)

| Symbol | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|--------|-------------|-------|-------|-----------------------|--------|--------|
|        | Min.        | Typ.  | Max.  | Min.                  | Typ.   | Max.   |
| L1     | -           | 1.040 | -     | -                     | 0.0409 | -      |
| ccc    | -           | -     | 0.100 | -                     | -      | 0.0039 |

1. Values in inches are converted from mm and rounded to four decimal digits.

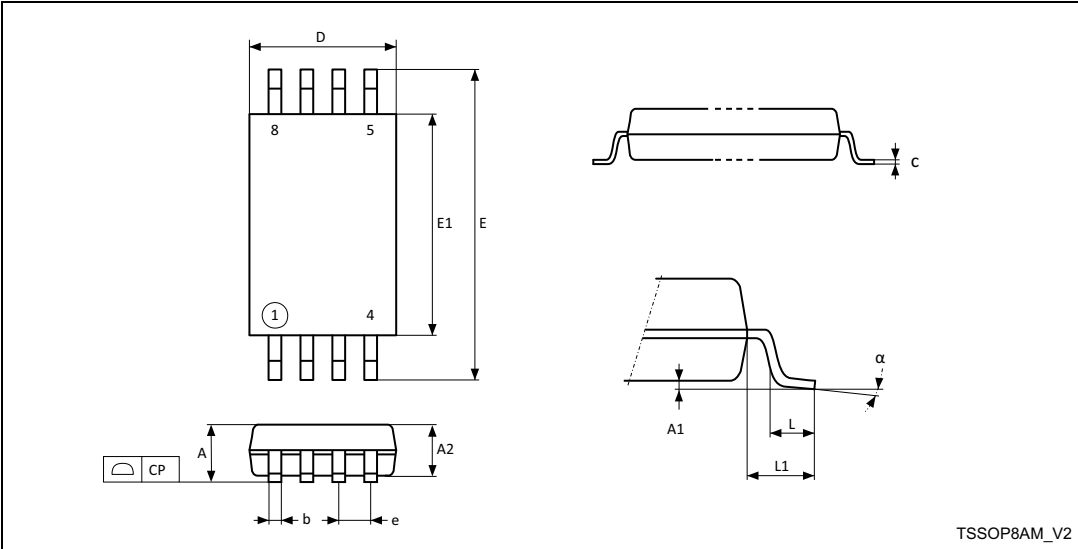
Figure 24. SO8N – 8-lead plastic small outline, 150 mils body width, package recommended footprint



1. Dimensions are expressed in millimeters.

# 10.2 TSSOP8 package information

Figure 25.TSSOP8 – 8-lead thin shrink small outline, 3 x 4.4 mm, 0.65 mm pitch, package outline



1. Drawing is not to scale.

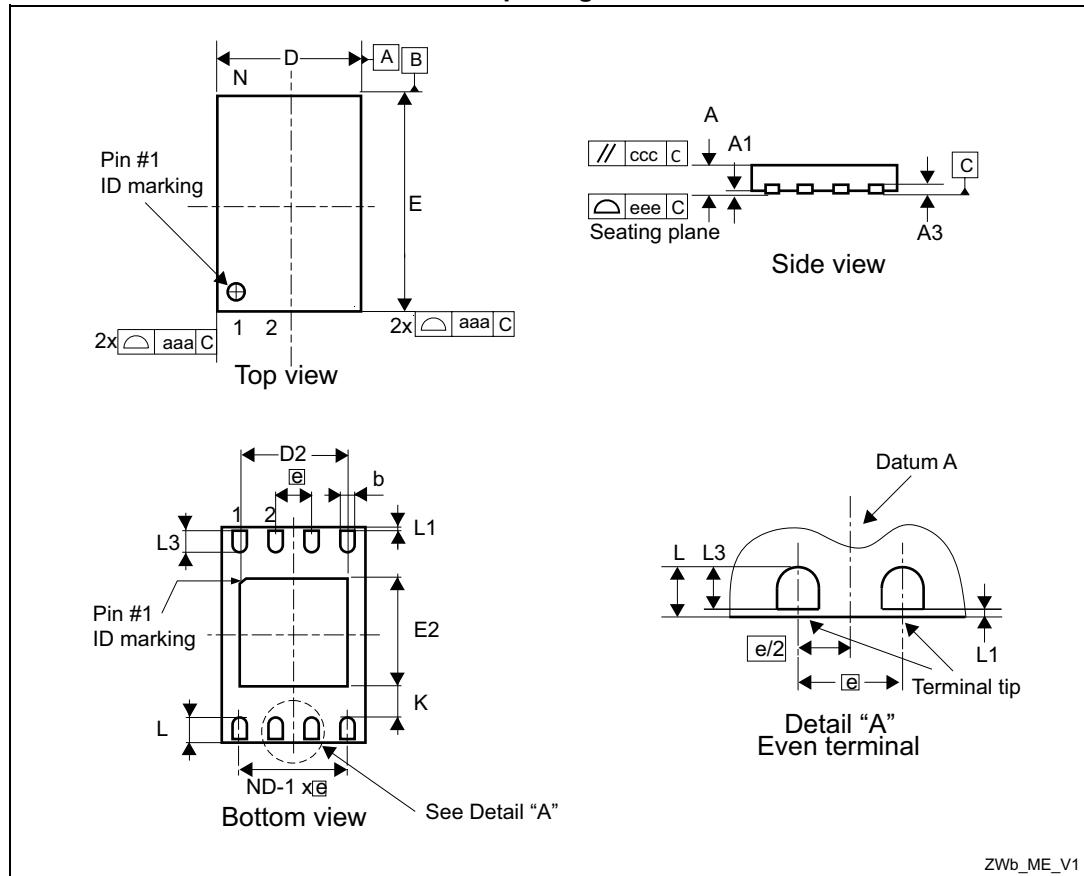
Table 22. TSSOP8 – 8-lead thin shrink small outline, 3 x 4.4 mm, 0.65 mm pitch, package mechanical data

| Symbol   | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|----------|-------------|-------|-------|-----------------------|--------|--------|
|          | Min.        | Typ.  | Max.  | Min.                  | Typ.   | Max.   |
| A        | -           | -     | 1.200 | -                     | -      | 0.0472 |
| A1       | 0.050       | -     | 0.150 | 0.0020                | -      | 0.0059 |
| A2       | 0.800       | 1.000 | 1.050 | 0.0315                | 0.0394 | 0.0413 |
| b        | 0.190       | -     | 0.300 | 0.0075                | -      | 0.0118 |
| c        | 0.090       | -     | 0.200 | 0.0035                | -      | 0.0079 |
| CP       | -           | -     | 0.100 | -                     | -      | 0.0039 |
| D        | 2.900       | 3.000 | 3.100 | 0.1142                | 0.1181 | 0.1220 |
| e        | -           | 0.650 | -     | -                     | 0.0256 | -      |
| E        | 6.200       | 6.400 | 6.600 | 0.2441                | 0.2520 | 0.2598 |
| E1       | 4.300       | 4.400 | 4.500 | 0.1693                | 0.1732 | 0.1772 |
| L        | 0.450       | 0.600 | 0.750 | 0.0177                | 0.0236 | 0.0295 |
| L1       | -           | 1.000 | -     | -                     | 0.0394 | -      |
| $\alpha$ | 0°          | -     | 8°    | 0°                    | -      | 8°     |

1. Values in inches are converted from mm and rounded to four decimal digits.

## 10.3 UDFN8 package information

Figure 26. UDFN8 - 8-lead, 2 × 3 mm, 0.5 mm pitch ultra thin profile fine pitch dual flat package outline



1. Max. package warpage is 0.05 mm.
2. Exposed copper is not systematic and can appear partially or totally according to the cross section.
3. Drawing is not to scale.
4. The central pad (the area E2 by D2 in the above illustration) must be either connected to  $V_{SS}$  or left floating (not connected) in the end application.

Table 23. UDFN8 - 8-lead, 2 × 3 mm, 0.5 mm pitch ultra thin profile fine pitch dual flat package mechanical data

| Symbol           | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|------------------|-------------|-------|-------|-----------------------|--------|--------|
|                  | Min         | Typ   | Max   | Min                   | Typ    | Max    |
| A                | 0.450       | 0.550 | 0.600 | 0.0177                | 0.0217 | 0.0236 |
| A1               | 0.000       | 0.020 | 0.050 | 0.0000                | 0.0008 | 0.0020 |
| b <sup>(2)</sup> | 0.200       | 0.250 | 0.300 | 0.0079                | 0.0098 | 0.0118 |
| D                | 1.900       | 2.000 | 2.100 | 0.0748                | 0.0787 | 0.0827 |
| D2               | 1.200       | -     | 1.600 | 0.0472                | -      | 0.0630 |
| E                | 2.900       | 3.000 | 3.100 | 0.1142                | 0.1181 | 0.1220 |

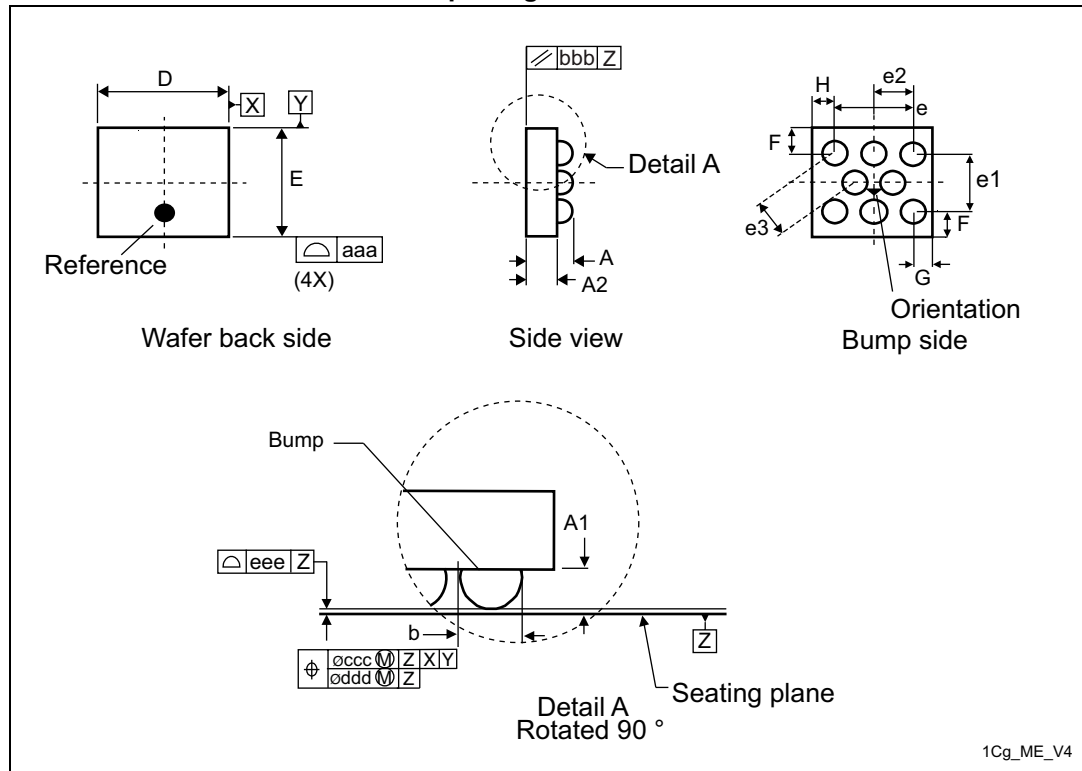
**Table 23. UFDFN8 - 8-lead, 2 × 3 mm, 0.5 mm pitch ultra thin profile fine pitch dual flat package mechanical data (continued)**

| Symbol             | millimeters |       |       | inches <sup>(1)</sup> |     |        |
|--------------------|-------------|-------|-------|-----------------------|-----|--------|
|                    | Min         | Typ   | Max   | Min                   | Typ | Max    |
| E2                 | 1.200       | -     | 1.600 | 0.0472                | -   | 0.0630 |
| e                  | -           | 0.500 | -     | 0.0197                |     |        |
| K                  | 0.300       | -     | -     | 0.0118                | -   | -      |
| L                  | 0.300       | -     | 0.500 | 0.0118                | -   | 0.0197 |
| L1                 | -           | -     | 0.150 | -                     | -   | 0.0059 |
| L3                 | 0.300       | -     | -     | 0.0118                | -   | -      |
| aaa                | -           | -     | 0.150 | -                     | -   | 0.0059 |
| bbb                | -           | -     | 0.100 | -                     | -   | 0.0039 |
| ccc                | -           | -     | 0.100 | -                     | -   | 0.0039 |
| ddd                | -           | -     | 0.050 | -                     | -   | 0.0020 |
| eee <sup>(3)</sup> | -           | -     | 0.080 | -                     | -   | 0.0031 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.
2. Dimension b applies to plated terminal and is measured between 0.15 and 0.30 mm from the terminal tip.
3. Applied for exposed die paddle and terminals. Exclude embedding part of exposed die paddle from measuring.

## 10.4 WLCSP package information

Figure 27. WLCSP - 8-bump, 1.289 x 1.376 mm, 0.4 mm pitch wafer level chip scale package outline



1. Drawing is not to scale.

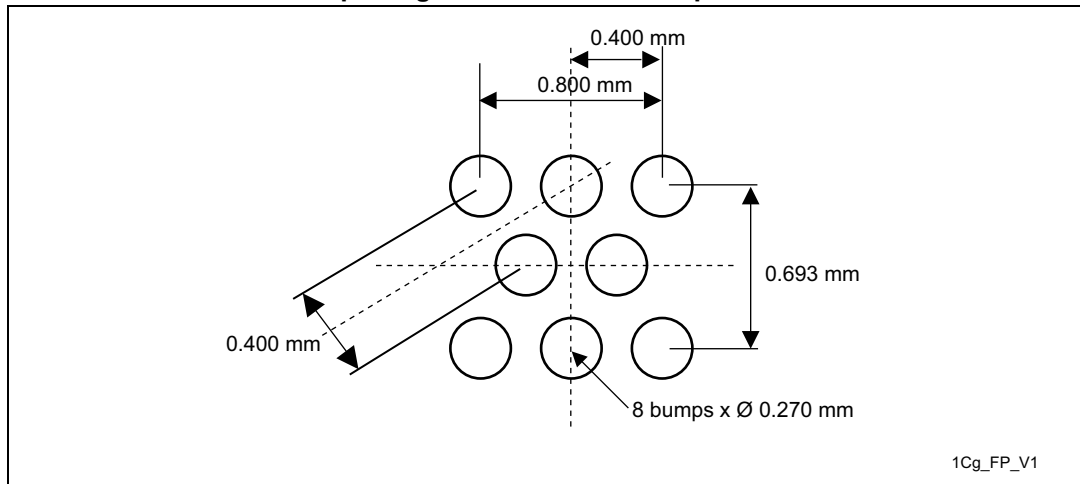
**Table 24. WLCSP - 8-bump, 1.289 x 1.376 mm, 0.4 mm pitch wafer level chip scale package mechanical data**

| Symbol           | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|------------------|-------------|-------|-------|-----------------------|--------|--------|
|                  | Min         | Typ   | Max   | Min                   | Typ    | Max    |
| A                | 0.500       | 0.540 | 0.580 | 0.0197                | 0.0213 | 0.0228 |
| A1               | -           | 0.190 | -     | -                     | 0.0075 | -      |
| A2               | -           | 0.350 | -     | -                     | 0.0138 | -      |
| b <sup>(2)</sup> | -           | 0.270 | -     | -                     | 0.0106 | -      |
| D                | -           | 1.289 | 1.309 | -                     | 0.0507 | 0.0515 |
| E                | -           | 1.376 | 1.396 | -                     | 0.0542 | 0.0550 |
| e                | -           | 0.800 | -     | -                     | 0.0315 | -      |
| e1               | -           | 0.693 | -     | -                     | 0.0273 | -      |
| e2               | -           | 0.400 | -     | -                     | 0.0157 | -      |
| e3               | -           | 0.400 | -     | -                     | 0.0157 | -      |
| F                | -           | 0.342 | -     | -                     | 0.0135 | -      |
| G                | -           | 0.245 | -     | -                     | 0.0096 | -      |
| H                | -           | 0.245 | -     | -                     | 0.0096 | -      |
| aaa              | -           | 0.110 | -     | -                     | 0.0043 | -      |
| bbb              | -           | 0.110 | -     | -                     | 0.0043 | -      |
| ccc              | -           | 0.110 | -     | -                     | 0.0043 | -      |
| ddd              | -           | 0.060 | -     | -                     | 0.0024 | -      |
| eee              | -           | 0.060 | -     | -                     | 0.0024 | -      |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

2. Dimension is measured at the maximum bump diameter parallel to primary datum Z.

**Figure 28. WLCSP - 8-bump, 1.289 x 1.376 mm, 0.4 mm pitch wafer level chip scale package recommended footprint**



1. Dimensions are expressed in millimeters.



# 11 Part numbering

**Table 25. Ordering information scheme**

|                                                                   |          |   |    |   |   |   |    |
|-------------------------------------------------------------------|----------|---|----|---|---|---|----|
| Example:                                                          | M95256-D | W | MN | 6 | T | P | /K |
| <b>Device type</b>                                                |          |   |    |   |   |   |    |
| M95 = SPI serial access EEPROM                                    |          |   |    |   |   |   |    |
| <b>Device function</b>                                            |          |   |    |   |   |   |    |
| 256 = 256 Kbit                                                    |          |   |    |   |   |   |    |
| <b>Device family</b>                                              |          |   |    |   |   |   |    |
| Blank = Without Identification page                               |          |   |    |   |   |   |    |
| D = With additional Identification page                           |          |   |    |   |   |   |    |
| <b>Operating voltage</b>                                          |          |   |    |   |   |   |    |
| W = $V_{CC} = 2.5$ to $5.5$ V                                     |          |   |    |   |   |   |    |
| R = $V_{CC} = 1.8$ to $5.5$ V                                     |          |   |    |   |   |   |    |
| F = $V_{CC} = 1.7$ to $5.5$ V                                     |          |   |    |   |   |   |    |
| <b>Package<sup>(1)</sup></b>                                      |          |   |    |   |   |   |    |
| MN = SO8 (150 mil width)                                          |          |   |    |   |   |   |    |
| DW = TSSOP8 (169 mil width)                                       |          |   |    |   |   |   |    |
| MC = UFD8FN8 (MLP8)                                               |          |   |    |   |   |   |    |
| CS = WLCSP                                                        |          |   |    |   |   |   |    |
| <b>Device grade</b>                                               |          |   |    |   |   |   |    |
| 6 = Industrial temperature range, $-40$ to $85$ °C                |          |   |    |   |   |   |    |
| Device tested with standard test flow                             |          |   |    |   |   |   |    |
| <b>Option</b>                                                     |          |   |    |   |   |   |    |
| T = Tape and reel packing                                         |          |   |    |   |   |   |    |
| blank = tube packing                                              |          |   |    |   |   |   |    |
| <b>Plating technology</b>                                         |          |   |    |   |   |   |    |
| G or P = RoHS compliant and halogen-free (ECOPACK2 <sup>®</sup> ) |          |   |    |   |   |   |    |
| <b>Process<sup>(2)</sup></b>                                      |          |   |    |   |   |   |    |
| /K = Manufacturing technology code                                |          |   |    |   |   |   |    |

1. All packages are ECOPACK2<sup>®</sup> (RoHS-compliant and free of brominated, chlorinated and antimony-oxide flame retardants).
2. The process letters apply to WLCSP devices only. The process letters appear on the device package (marking) and on the shipment box. Please contact your nearest ST Sales Office for further information.

*Note: Parts marked as “ES”, “E” or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.*

## 12 Revision history

**Table 26. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                  |
|-------------|----------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 17-Nov-1999 | 2.1      | New -V voltage range added (including the tables for DC characteristics, AC characteristics, and ordering information).                                                                  |
| 07-Feb-2000 | 2.2      | New -V voltage range extended to M95256 (including AC characteristics, and ordering information).                                                                                        |
| 22-Feb-2000 | 2.3      | tCLCH and tCHCL, for the M95xxx-V, changed from 1μs to 100ns                                                                                                                             |
| 15-Mar-2000 | 2.4      | -V voltage range changed to 2.7-3.6V                                                                                                                                                     |
| 29-Jan-2001 | 2.5      | Lead Soldering Temperature in the Absolute Maximum Ratings table amended<br>Illustrations and Package Mechanical data updated                                                            |
| 12-Jun-2001 | 2.6      | Correction to header of Table 12B<br>TSSOP14 Illustrations and Package Mechanical data updated<br>Document promoted from Preliminary Data to Full Data Sheet                             |
| 08-Feb-2002 | 2.7      | Announcement made of planned upgrade to 10 MHz clock for the 5V, -40 to 85°C, range.                                                                                                     |
| 09-Aug-2002 | 2.8      | M95128 split off to its own datasheet. Data added for new and forthcoming products, including availability of the SO8 narrow package.                                                    |
| 24-Feb-2003 | 2.9      | Omission of SO8 narrow package mechanical data remedied                                                                                                                                  |
| 26-Jun-2003 | 2.10     | -V voltage range removed                                                                                                                                                                 |
| 21-Nov-2003 | 3.0      | Table of contents, and Pb-free options added. -S voltage range extended to -R. $V_{IL}(\min)$ improved to -0.45V                                                                         |
| 17-Mar-2004 | 4.0      | Absolute Maximum Ratings for $V_{IO}(\min)$ and $V_{CC}(\min)$ changed. Soldering temperature information clarified for RoHS compliant devices. Device grade information clarified       |
| 21-Oct-2004 | 5.0      | M95128 datasheet merged back in. Product List summary table added. AEC-Q100-002 compliance. Device Grade information clarified. tHHQX corrected to tHHQV. 10MHz product becomes standard |

Table 26. Document revision history (continued)

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
|-------------|----------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 13-Apr-2006 | 6        | <p>M95128 part numbers removed from document. PDIP8 package removed.</p> <p><a href="#">Delivery state</a> paragraph added.</p> <p><a href="#">Section 3.8: Operating supply voltage (VCC)</a> added and information removed below <a href="#">Section 4: Operating features</a>.</p> <p>Power up state removed below <a href="#">Section 6: Delivery state</a>.</p> <p><a href="#">Figure 18: SPI modes supported</a> modified and <a href="#">Note 2</a> added.</p> <p><a href="#">Note 1</a> added to <a href="#">Table 8</a>.</p> <p><math>I_{CC1}</math> specified over the whole <math>V_{CC}</math> range and <math>I_{CC0}</math> added in <a href="#">Table 14</a>, <a href="#">Table 15</a> and <a href="#">Table 16</a>. <math>I_{CC}</math> specified over the whole <math>V_{CC}</math> range in <a href="#">Table 14</a>.</p> <p><a href="#">Table 17: AC Characteristics (M95256, Device Grade 6)</a> added.</p> <p><math>t_{CHHL}</math> and <math>t_{CHHH}</math> replaced by <math>t_{CLHL}</math> and <math>t_{CLHH}</math>, respectively.</p> <p><a href="#">Figure 21: Hold timing</a> modified. <a href="#">Process</a> added to <a href="#">Table 25: Ordering information scheme</a>. <a href="#">Note 1</a> added to <a href="#">Table 25</a>.</p> <p><a href="#">Note 1</a> removed from <a href="#">Table 20: AC characteristics (M95256-DR, M95256-R device grade 6)</a>.</p> <p><math>T_A</math> added to <a href="#">Table 7: Absolute maximum ratings</a>.</p> <p>Order of sections modified.</p> |
| 15-Oct-2007 | 7        | <p>M95256 with device grade 6 temperature range removed.</p> <p><a href="#">Section 3.7: VSS ground</a> added, <a href="#">Section 3.8: Operating supply voltage (VCC)</a> modified. Small text changes.</p> <p><a href="#">Section 5.4: Write Status Register (WRSR)</a>, <a href="#">Section 5.5: Read from Memory Array (READ)</a> and <a href="#">Section 6: Delivery state</a> updated.</p> <p><a href="#">Note 2</a> below <a href="#">Figure 17: Bus master and memory devices on the SPI bus</a> removed, replaced by explanatory paragraph.</p> <p><math>T_{LEAD}</math> added to <a href="#">Table 7: Absolute maximum ratings</a>.</p> <p>Test conditions modified for <math>I_{CC0}</math> and <math>I_{CC1}</math>, and <math>V_{IH}</math> min modified in <a href="#">Table 17: AC characteristics (M95256, device grade 3)</a>.</p> <p><math>t_W</math> modified and "preliminary data" note removed in <a href="#">Table 20: AC characteristics (M95256-DR, M95256-R device grade 6)</a>.</p> <p>Blank option removed below Plating technology, process A modified and process V removed in <a href="#">Table 25: Ordering information scheme</a>.</p> <p><a href="#">Table 26: Available M95256x products (package, voltage range, temperature grade)</a> added.</p> <p>SO8N and SO8W package specifications updated (see <a href="#">Section 10: Package mechanical data</a>). Package mechanical data: inches calculated from mm and rounded to 3 decimal digits.</p>                                        |
| 27-Mar-2008 | 8        | <p><a href="#">Section 3.8: Operating supply voltage (VCC)</a> modified. Small text changes. Frequency corrected on <a href="#">page 1</a>.</p> <p><math>V_{IL}</math> and <math>V_{IH}</math> modified in <a href="#">Table 16: DC characteristics (M95256-R, M95256-DR, device grade 6)</a>.</p> <p>AB Process added to <a href="#">Table 25: Ordering information scheme</a>.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| 15-Jul-2008 | 9        | <p>WLCSP package added (see <a href="#">Figure 3: WLCSP connections (top view, marking side, with balls on the underside)</a> and <a href="#">Section 10: Package mechanical data</a>).</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |

Table 26. Document revision history (continued)

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
|-------------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 24-Jun-2010 | 10       | <p>M95512 part number added.</p> <p>Updated <a href="#">Section 3.8: Operating supply voltage (VCC)</a></p> <p>Updated <a href="#">Section 4.3: Data protection and protocol control</a></p> <p>Updated <a href="#">Section 5.4: Write Status Register (WRSR)</a></p> <p>Added note in <a href="#">Section 5.6: Write to Memory Array (WRITE)</a></p> <p>Updated <a href="#">Table 7: Absolute maximum ratings</a></p> <p>Added <a href="#">Table 20: AC characteristics (M95256-DR, M95256-R device grade 6)</a></p> <p>Updated <a href="#">Table 20: AC characteristics (M95256-DR, M95256-R device grade 6)</a></p>                                    |
| 07-Sep-2010 | 11       | <p>Updated <a href="#">Section 1: Description</a>.</p> <p>Updated <a href="#">Section 5.7: Read Identification Page (available only in M95256-DR devices)</a>.</p> <p>Updated <a href="#">Section 5.8: Write Identification Page</a>.</p> <p>Updated <a href="#">Section 5.9: Read Lock Status (available only in M95256-DR devices)</a>.</p>                                                                                                                                                                                                                                                                                                             |
| 12-Nov-2010 | 12       | <p>Updated <a href="#">Features</a>.</p> <p>Updated <a href="#">Section 5.8: Write Identification Page</a>.</p> <p>Added <a href="#">Figure 25: TSSOP8 – 8 lead thin shrink small outline, package outline</a>.</p> <p>Added <a href="#">Table 23: UFDFPN8 (MLP8) – 8-lead ultra thin fine pitch dual flat package no lead 2 × 3 mm, package mechanical data</a>.</p> <p>Updated <a href="#">Section 11: Part numbering</a>.</p> <p>Updated <a href="#">Table 26: Available M95256x products (package, voltage range, temperature grade)</a>.</p> <p>Updated <a href="#">Figure 25, Figure 26</a>.</p>                                                    |
| 22-Mar-2011 | 13       | <p>Deleted:</p> <ul style="list-style-type: none"> <li>– SO8 (MW) picture under <a href="#">Features</a></li> <li>– SO8 (MW) mechanical dimensions</li> </ul> <p>Updated:</p> <ul style="list-style-type: none"> <li>– UFDFPN8 (MB) with UFDFPN8 (MB, MC) picture under <a href="#">Features</a></li> <li>– <a href="#">Section 5.6.1: ECC (error correction code) and Write cycling</a></li> <li>– <a href="#">Section 7: Connecting to the SPI bus</a></li> <li>– <a href="#">Table 7: Absolute maximum ratings</a></li> </ul> <p>Process letter K substituted with only concerned products (M95256-D and M95256 in MLP8 package MC).9</p> <p>(...)</p> |

Table 26. Document revision history (continued)

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
|-------------|----------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 22-Mar-2011 | 13       | <p>(...)</p> <ul style="list-style-type: none"> <li>Rephrased “test condition” text in: <ul style="list-style-type: none"> <li><a href="#">Table 14: DC characteristics (M95256, device grade 3)</a></li> <li><a href="#">Table 20: DC characteristics (current M95080-W products)</a></li> <li><a href="#">Table 16: DC characteristics (M95256-W, device grade 3)</a></li> <li><a href="#">Table 23: DC characteristics (current and new M95080-R and M95080-DR products)</a></li> <li><a href="#">Table 18: AC characteristics (M95256, device grade 3)</a></li> <li><a href="#">Table 31: AC characteristics, M95080-W, device grade 6</a></li> <li><a href="#">Table 20: AC characteristics (M95256-W, device grade 3)</a></li> <li><a href="#">Table 36: AC characteristics (M95080-R, M95080-DR device grade 6)</a></li> </ul> </li> </ul> <p>Added:</p> <ul style="list-style-type: none"> <li>Caution under <a href="#">Figure 3: WLCSP connections (top view, marking side, with balls on the underside)</a></li> <li>MC = UFDFPN8 package in <a href="#">Section 11: Part numbering</a></li> </ul> |
| 20-May-2011 | 14       | <p>Updated:</p> <ul style="list-style-type: none"> <li>UFDFPN8 offered in only one package version</li> </ul> <p>Added:</p> <ul style="list-style-type: none"> <li><a href="#">Table 15: Memory cell characteristics</a></li> </ul>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| 19-Jul-2011 | 15       | MC package added (UFDFPN8)                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
| 23-Nov-2011 | 16       | <p>Updated:</p> <ul style="list-style-type: none"> <li>Footnote 3 below <a href="#">Table 7: Absolute maximum ratings</a></li> <li>Footnotes 1, 2, 4, 5 below <a href="#">Table 15: DC characteristics (M95256-W, device grade 6)</a></li> <li>Footnotes 1, 2, 3, 5 below <a href="#">Table 17: DC characteristics (M95256-R, M95256-DR, device grade 6)</a></li> <li><a href="#">Table 19: AC characteristics, M95256-W, device grade 6</a> headings, <math>T_{QLQH}</math> and <math>T_{QHQL}</math> values. One footnote removed and one added</li> <li><a href="#">Table 21: AC characteristics (M95256-DR, M95256-R device grade 6)</a>, new columns for new pairs of products. Footnote 2 edited.</li> </ul>                                                                                                                                                                                                                                                                                                                                                                                            |
| 17-Jan-2012 | 17       | Updated <a href="#">Figure 25: UFDFPN8 (MLP8) - 8-lead ultra thin fine pitch dual flat no lead, package outline</a> .                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
| 21-Jun-2012 | 18       | <p>Datasheet split into:</p> <ul style="list-style-type: none"> <li>M95256-125 datasheet for automotive products (range 3),</li> <li>M95256-W, M95256-R, M95256-DR, M95256-DF (this datasheet) for standard products (range 6).</li> </ul> <p>Added:</p> <ul style="list-style-type: none"> <li>1.7 V device (M95256-DF)</li> </ul> <p>Updated:</p> <ul style="list-style-type: none"> <li><a href="#">Figure 15: Block diagram</a></li> <li><a href="#">Table 58: M95080-DFCS6TP/K, WLCSP 8-bump wafer-level chip scale package mechanical data</a> and <a href="#">Figure 42: M95080-DFCS6TP/K, WLCSP 8-bump wafer-level chip scale package outline</a></li> <li>Cycling and data retention values (<a href="#">Table 19</a> and <a href="#">Table 20</a>)</li> </ul> <p>Deleted:</p> <ul style="list-style-type: none"> <li>UFDFPN8 package rev MB</li> </ul>                                                                                                                                                                                                                                              |

Table 26. Document revision history (continued)

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
|-------------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 24-Jul-2012 | 19       | Updated:<br>– WLCSP package reference from “CT” to “CS”<br>– <i>Figure 3: WLCSP connections (top view, marking side, with bumps on the underside)</i><br>– <i>Figure 42: M95080-DFCS6TP/K, WLCSP 8-bump wafer-level chip scale package outline.</i>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
| 09-Apr-2013 | 20       | Document reformatted.<br>Updated:<br>– Package figure on cover page<br>– <i>Section 7.2: Initial delivery state</i><br>– Note <sup>(1)</sup> in <i>Table 7: Absolute maximum ratings</i><br>Deleted former footnote 1 in <i>Table 17: DC characteristics (M95256-DF, device grade 6)</i><br>Replaced “ball” by “bump” in the entire document.                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
| 06-Mar-2017 | 21       | Removed obsolete product M95256-DR.<br>Updated <i>Features</i> , <i>Section 1: Description</i> and <i>Section 6: Instructions</i> .<br>Updated <i>Figure 1: Logic diagram</i> , <i>Figure 3: WLCSP connections (top view, marking side, with bumps on the underside)</i> , <i>Figure 4: Block diagram</i> , <i>Figure 6: SPI modes supported</i> , <i>Figure 8: Write Enable (WREN) sequence</i> and <i>Figure 9: Write Disable (WRDI) sequence</i> .<br>Updated <i>Table 1: Signal names</i> , tables in <i>Section 6: Instructions</i> and <i>Table 11: AC measurement conditions</i> .<br>Updated footnote 2 of <i>Table 7: Absolute maximum ratings</i> and added footnote 6 to <i>Table 15: DC characteristics (M95256-W, device grade 6)</i> .<br>Updated <i>Section 10: Package information</i> and its subsections. |

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